

14-Pin, 8-Bit Flash Microcontroller

High-Performance RISC CPU

- · Only 34 Single-Word Instructions
- All Single-Cycle Instructions except for Program Branches which are Two-Cycle
- · Four-Level Deep Hardware Stack
- Direct, Indirect and Relative Addressing modes for Data and Instructions
- · Operating Speed:
 - DC 8 MHz internal clock
 - DC 500 ns instruction cycle

Special Microcontroller Features

- 8 MHz Precision Internal Oscillator:
 - Factory-calibrated to ±1%
- In-Circuit Serial Programming™ (ICSP™)
- Power-on Reset (POR)
- · Device Reset Timer (DRT)
- Watchdog Timer (WDT) with Dedicated On-Chip RC Oscillator for Reliable Operation
- · Programmable Code Protection
- Multiplexed MCLR Input Pin
- · Internal Weak Pull-ups on I/O Pins
- · Power-Saving Sleep mode
- · Wake-up from Sleep on Pin Change
- · Selectable Oscillator Options:
 - INTRC: 4 MHz or 8 MHz precision internal RC oscillator
 - EXTRC: External low-cost RC oscillator
 - XT: Standard crystal/resonator
 - LP: Power-saving, low-frequency crystal

Low-Power Features/CMOS Technology

- · Standby Current:
 - 225 nA @ 2.0V, RF Sleep, typical
- · Operating Current:
 - 175 μA @ 4 MHz, 2.0V, RF Sleep, typical
 - 9.17 mA @ 4 MHz, 2.0V, RF on at +0 dBm, typical
 - 15.17 mA @ 4 MHz, 2.0V, RF on at +10 dBm, typical
- Watchdog Timer Current:
 - 1 μA @ 2.0V, typical
- High Endurance Program and Flash Data Memory cells:
 - 100,000 write program memory endurance
 - 1,000,000 write Flash data memory endurance
 - Program and Flash data retention: >40 years
- · Fully Static Design
- · Operating Voltage Range: 2.0V to 3.7V
- Industrial temperature range: -40°C to +85°C

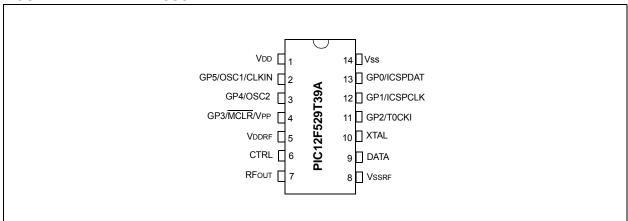
RF Transmitter

- · Fully-Integrated Transmitter
- FSK Operation up to 100 kbps
- OOK Operation up to 10 kbps
- Frequency-Agile Operation in 310, 433, 868 and 915 MHz bands
- Configurable Output Power: +10 dBm, 0 dBm

Peripheral Features

- · Six I/O Pins:
 - Five I/O pins with individual direction control
 - One input-only pin
 - High-current sink/source for direct LED drive
- 8-Bit Real-Time Clock/Counter (TMR0) with 8-Bit Programmable Prescaler

FIGURE 1: 14-PIN TSSOP



PIC12F529T39A Family Types

Device	Program Memory	Data Memory		UO PE Transmitter		Commonstone	Timers	8-Bit A/D
Device	Flash (words)	SRAM (bytes)	Flash (bytes)	I/O	RF Transmitter	Comparators	(8-bit)	Channels
PIC12F529T39A	1536	201	64	6	1	0	1	0
PIC12LF1840T39A								

Data Sheet Index: (Unshaded devices are described in this document.)

1: DS40001636 PIC12LF1840T39A Data Sheet, 8-Bit Flash Microcontroller with XLP

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1.0 GENERAL DESCRIPTION

The PIC12F529T39A device from Microchip Technology is a low-cost, high-performance, 8-bit, fully-static, Flash-based CMOS microcontroller. It employs a RISC architecture with only 34 single-word/ single-cycle instructions. All instructions are single cycle except for program branches, which take two cycles. The PIC12F529T39A device delivers performance an order of magnitude higher than its competitors in the same price category. The 12-bit wide instructions are highly symmetrical, resulting in a typical 2:1 code compression over other 8-bit microcontrollers in its class. The easy-to-use and easy to remember instruction set reduces development time significantly.

The PIC12F529T39A product is equipped with special features that reduce system cost and power requirements. The Power-on Reset (POR) and Device Reset Timer (DRT) eliminate the need for external Reset circuitry. There are four oscillator configurations to choose from including INTRC Internal Oscillator mode and the power-saving LP (Low-power) Oscillator mode. Power-Saving Sleep mode, Watchdog Timer and code protection features improve system cost, power and reliability.

The PIC12F529T39A device is available in the costeffective Flash programmable version, which is suitable for production in any volume. The customer can take full advantage of Microchip's price leadership in Flash programmable microcontrollers, while benefiting from the Flash programmable flexibility.

The PIC12F529T39A product is supported by a full-featured macro assembler, a software simulator, a low-cost development programmer and a full-featured programmer. All the tools are supported on PC and compatible machines.

1.1 Applications

The PIC12F529T39A device fits in applications ranging from personal care appliances and security systems to low-power remote transmitters/receivers. The Flash technology makes customizing application programs (transmitter codes, appliance settings, receiver frequencies, etc.) extremely fast and convenient. The small footprint packages, for through hole or surface mounting, make these microcontrollers perfect for applications with space limitations. Low cost, low power, high performance, ease of use and I/O flexibility make the PIC12F529T39A device very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions, logic and PLDs in larger systems and co-processor applications).

TABLE 1-1: FEATURES AND MEMORY OF PIC12F529T39A

		PIC12F529T39A
Clock	Maximum Frequency of Operation (MHz)	8
Memory	Flash Program Memory	1536
	SRAM Data Memory (bytes)	201
	Flash Data Memory (bytes)	64
Peripherals	Timer Module(s)	TMR0
	Wake-up from Sleep on Pin Change	Yes
Features	I/O Pins	5
	Input Pins	1
	Internal Pull-ups	Yes
	In-Circuit Serial Programming™	Yes
	Number of Instructions	34
	RF Transmitter Frequency Range	310 MHz, 433 MHz, 868 MHz and 915 MHz Bands
	Packages	14-pin TSSOP

2.0 PIC12F529T39A DEVICE VARIETIES

When placing orders, please use the PIC12F529T39A Product Identification System at the back of this data sheet to specify the correct part number. Depending on application and production requirements, the proper device option can be selected using the information in this section.

2.1 Quick-Turn Programming (QTP) Devices

Microchip offers a QTP programming service for factory production orders. This service is made available for users who choose not to program medium-to-high quantity units and whose code patterns have stabilized. The devices are identical to the Flash devices but with all Flash locations and fuse options already programmed by the factory. Certain code and prototype verification procedures do apply before production shipments are available. Please contact your local Microchip Technology sales office for more details.

2.2 Serialized Quick-Turn ProgrammingSM (SQTPSM) Devices

Microchip offers a unique programming service, where a few user-defined locations in each device are programmed with different serial numbers. The serial numbers may be random, pseudo-random or sequential.

Serial programming allows each device to have a unique number, which can serve as an entry code, password or ID number.

3.0 ARCHITECTURAL OVERVIEW

The high performance of the PIC12F529T39A device can be attributed to a number of architectural features commonly found in RISC microprocessors. To begin with, the PIC12F529T39A device uses a Harvard architecture in which program and data are accessed on separate buses. This improves bandwidth over traditional von Neumann architectures where program and data are fetched on the same bus. Separating program and data memory further allows instructions to be sized differently than the 8-bit wide data word. Instruction opcodes are 12 bits wide, making it possible to have all single-word instructions. A 12-bit wide program memory access bus fetches a 12-bit instruction in a single cycle. A two-stage pipeline overlaps fetch and execution of instructions. Consequently, all instructions (34) execute in a single cycle (500 ns @ 8 MHz, 1 μs @ 4 MHz) except for program branches.

Table 3-1 below lists memory supported by the PIC12F529T39A device.

TABLE 3-1: PIC12F529T39A MEMORY

	Program Memory	Data Memory		
Device	Flash (words)	SRAM (bytes)	Flash Data (bytes)	
PIC12F529T39A	1536	201	64	

The PIC12F529T39A device can directly or indirectly address its register files and data memory. All Special Function Registers (SFR), including the PC, are mapped in the data memory. The PIC12F529T39A device has a highly orthogonal (symmetrical) instruction set that makes it possible to carry out any operation, on any register, using any addressing mode. This symmetrical nature and lack of "special optimal situations" make programming with the PIC12F529T39A device simple, yet efficient. In addition, the learning curve is reduced significantly.

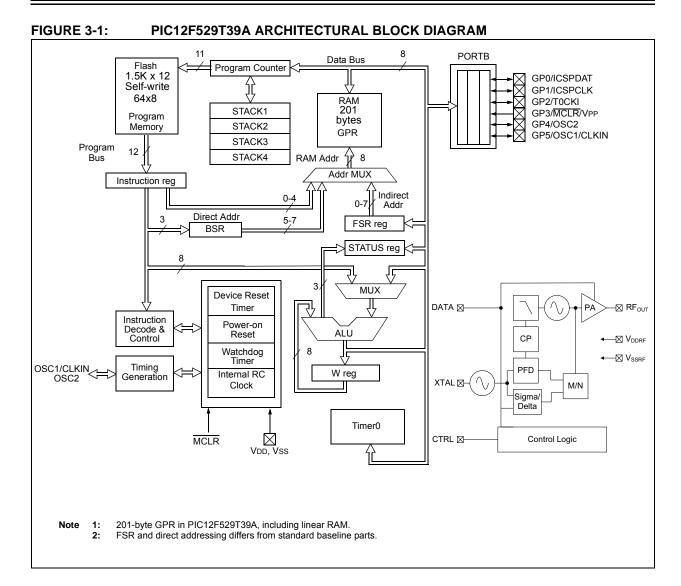
The PIC12F529T39A device contains an 8-bit ALU and working register. The ALU is a general purpose arithmetic unit. It performs arithmetic and Boolean functions between data in the working register and any register file.

The ALU is 8-bit wide and capable of addition, subtraction, shift and logical operations. Unless otherwise mentioned, arithmetic operations are two's complement in nature. In two-operand instructions, one operand is typically the W (working) register. The other operand is either a file register or an immediate constant. In single-operand instructions, the operand is either the W register or a file register.

The W register is an 8-bit working register used for ALU operations. It is not an addressable register.

Depending on the instruction executed, the ALU may affect the values of the Carry (C), Digit Carry (DC) and Zero (Z) bits in the STATUS register. The C and DC bits operate as a borrow and digit borrow out bit, respectively, in subtraction. See the SUBWF and ADDWF instructions for examples.

A simplified block diagram is shown in Figure 3-1, with the corresponding device pins described in Table 3-2.



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TABLE 3-2: PIC12F529T39A PINOUT DESCRIPTION

Name	Function	Туре	Input Type	Output Type	Description
GP0/ICSPDAT	GP0	I/O	TTL	CMOS	Bidirectional I/O port with weak pull-up.
	ICSPDAT	I/O	ST	CMOS	ICSP™ mode Schmitt Trigger.
GP1/ICSPCLK GP1 I/O TTL CMOS		CMOS	Bidirectional I/O port with weak pull-up.		
	ICSPCLK	I	ST	_	ICSP™ mode Schmitt Trigger.
GP2/T0CKI	GP2	I/O	TTL	CMOS	Bidirectional I/O port.
	T0CKI	I	ST	_	Timer0 clock input.
GP3/MCLR/VPP	GP3	I	TTL	_	Standard TTL input with weak pull-up.
	MCLR	I	ST	_	MCLR input (weak pull-up always enabled in this mode).
	VPP	I	High Voltage	_	Test mode high-voltage pin.
GP4/OSC2	GP4	I/O	TTL	CMOS	Bidirectional I/O port.
	OSC2	0	_	XTAL	XTAL oscillator output pin for microcontroller.
GP5/OSC1/	GP5	I/O	TTL	CMOS	Bidirectional I/O port.
CLKIN	OSC1	I	XTAL	_	XTAL oscillator input pin for microcontroller.
	CLKIN	I	ST	_	EXTRC Schmitt Trigger input.
VDD	Vdd	Р	Power	_	Positive supply for logic and I/O pins.
Vss	Vss	Р	Power	_	Ground reference for logic and I/O pins.
VDDRF	VDDRF	Р	Power	_	Positive Power Supply for RF Transmitter.
CTRL	CTRL	I	CMOS	_	Configuration Selection and Configuration Clock.
RFout	RFout	0	_	RF	Transmitter RF output.
Vssrf	Vssrf	Р	Power	_	Ground reference for RF Transmitter.
DATA	DATA	I/O	CMOS	CMOS	Configuration Data and Transmit Data.
XTAL	XTAL	ı	XTAL	_	Crystal oscillator input pin for RF Transmitter.

Legend: I = Input, O = Output, I/O = Input/Output, P = Power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input, AN = Analog Voltage

3.1 Clocking Scheme/Instruction Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the PC is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow is shown in Figure 3-2 and Example 3-1.

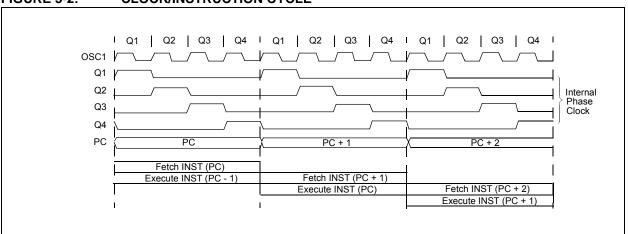
3.2 Instruction Flow/Pipelining

An instruction cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute take another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the PC to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

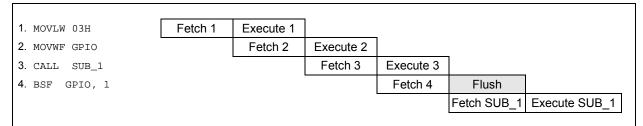
A fetch cycle begins with the PC incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register (IR) in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

FIGURE 3-2: CLOCK/INSTRUCTION CYCLE



EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



All instructions are single cycle, except for any program branches. These take two cycles, since the fetch instruction is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

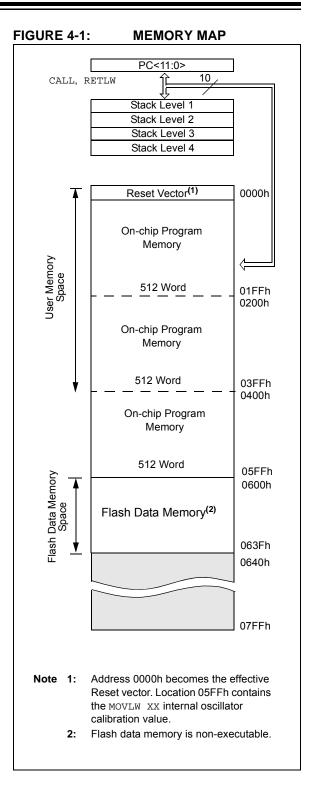
4.0 MEMORY ORGANIZATION

The PIC12F529T39A memory is organized into program memory and data memory (SRAM). The self-writable portion of the program memory called Flash data memory, is located at addresses 600h-63Fh. As the device has more than 512 bytes of program memory, a paging scheme is used. Program memory pages are accessed using STATUS register bit, PA0. For the PIC12F529T39A, with data memory register files of more than 32 registers, a banking scheme is used. Data memory banks are accessed using the File Select Register (FSR).

4.1 Program Memory Organization for the PIC12F529T39A

The PIC12F529T39A device has an 11-bit Program Counter (PC) capable of addressing a 2K x 12 program memory space.

Only the first 1.5K x 12 (0000h-05FFh) are physically implemented (see Figure 4-1). Accessing a location above these boundaries will cause a wrap-around within the 1.5K x 12 space. The effective Reset vector is a 0000h (see Figure 4-1). Location 05FFh contains the internal clock oscillator calibration value. This value should never be overwritten.



4.2 Data Memory (SRAM and FSRs)

Data memory is composed of registers or bytes of SRAM. Therefore, data memory for a device is specified by its register file. The register file is divided into two functional groups: Special Function Registers (SFR) and General Purpose Registers (GPR).

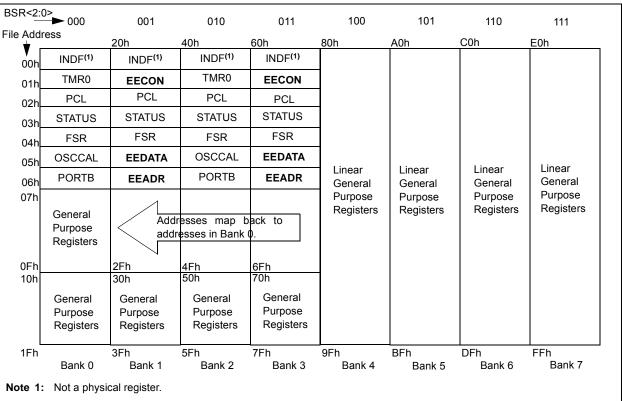
The Special Function Registers include the TMR0 register, the Program Counter Low (PCL), the STATUS register, the I/O register (port) and the File Select Register (FSR). In addition, the EECON, EEDATA and EEADR registers provide for interface with the Flash data memory.

The PIC12F529T39A register file is composed of 10 Special Function Registers and 201 General Purpose Registers.

4.2.1 GENERAL PURPOSE REGISTER FILE

The General Purpose Register file is accessed, either directly or indirectly, through the File Select Register (FSR). See Section 4.8 "Indirect Data Addressing: INDF and FSR Registers".

FIGURE 4-2: REGISTER FILE MAP



4.2.2 SPECIAL FUNCTION REGISTERS

The Special Function Registers (SFRs) are registers used by the CPU and peripheral functions to control the operation of the device (Table 4-1).

The Special Function Registers can be classified into two sets. The Special Function Registers associated with the "core" functions are described in this section. Those related to the operation of the peripheral features are described in the section for each peripheral feature.

4.2.3 LINEAR RAM

The last four banks, addresses 0x80 to 0xFF, are general purpose RAM registers, unbroken by SFRs. This region is ideal for indirect access using the FSR and INDF registers.

Note: Unlike other baseline devices, the FSR register does not contain bank bits and, therefore, does not affect direct addressing schemes. The FSR/INDF registers have full access to RAM.

TABLE 4-1: SPECIAL FUNCTION REGISTER SUMMARY

Addr	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset
N/A	TRIS	_	_	TRISGPI05	TRISGPI04	TRISGPI03	TRISGPI02	TRISGPI01	TRISGPI00	11 1111
N/A	OPTION	Contains C	ontrol Bits to	o Configure Tin	ner0 and Time	0/WDT Presca	ler			1111 1111
N/A	BSR	_	_	_	_	_		BSR<2:0>		000
00h	INDF	Uses Conte	Uses Contents of FSR to Address Data Memory (not a physical register)							xxxx xxxx
01h	TMR0	Timer0 Mo	Timer0 Module Register							xxxx xxxx
02h ⁽¹⁾	PCL	Low Order	Low Order 8 bits of PC							1111 1111
03h	STATUS	GPWUF	PA1	PA0	TO	PD	Z	DC	С	0001 1xxx
04h	FSR	Indirect Da	ta Memory A	Address Pointe	r					110x xxxx
05h	OSCCAL	CAL6	CAL5	CAL4	CAL3	CAL2	CAL1	CAL0	_	1111 111-
06h	GPIO	_	_	GP5	GP4	GP3	GP2	GP1	GP0	xx xxxx
21h	EECON	_	_	_	FREE	WRERR	WREN	WR	RD	0 x000
25h	EEDATA	EEDATA7	EEDA- TA6	EEDATA5	EEDATA4	EEDATA3	EEDATA2	EEDATA1	EEDATA0	xxxx xxxx
26h	EEADR	_	_	EEADR5	EEADR4	EEADR3	EEADR2	EEADR1	EEADR0	xx xxxx

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0' (if applicable). Shaded cells = unimplemented or unused
 Note 1: The upper byte of the Program Counter is not directly accessible. See Section 4.6 "Program Counter" for an explanation of how to

x = Bit is unknown

4.3 STATUS Register

Legend:

R = Readable bit

-n = Value at POR

This register contains the arithmetic status of the ALU, the Reset status and the page preselect bit.

The STATUS register can be the destination for any instruction, as with any other register. If the STATUS register is the destination for an instruction that affects the Z, DC or C bits, then the write to these three bits is disabled. These bits are set or cleared according to the device logic. Furthermore, the $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits are not writable. Therefore, the result of an instruction with the STATUS register as destination may be different than intended.

For example, CLRF STATUS, will clear the upper three bits and set the Z bit. This leaves the STATUS register as '000u uluu' (where u = unchanged).

Therefore, it is recommended that only BCF, BSF and MOVWF instructions be used to alter the STATUS register. These instructions do not affect the Z, DC or C bits from the STATUS register. For other instructions which do affect Status bits, see Section 10.0 "Instruction Set Summary".

REGISTER 4-1: STATUS: STATUS REGISTER

W = Writable bit

'1' = Bit is set

R/W-0	R/W-0	R/W-0	R-1	R-1	R/W-x	R/W-x	R/W-x
GPWUF	PA1	PA0	TO	PD	Z	DC	С
bit 7							bit 0

U = Unimplemented bit, read as '0'

'0' = Bit is cleared

bit 7	GPWUF : Wake-up From Sleep on Pin Change bit 1 = Reset due to wake-up from Sleep on pin change 0 = After power-up or other Reset
bit 6-5	PA<1:0>: Program Page Preselect bits ⁽¹⁾ 00 = Page 0 (000h-1FFh) 01 = Page 1 (200h-3FFh) 10 = Page 2 (400h-5FFh) 11 = Reserved. Do not use.
bit 4	TO: Time-Out bit 1 = After power-up, CLRWDT instruction, or SLEEP instruction 0 = A WDT time-out occurred
bit 3	PD: Power-Down bit 1 = After power-up or by the CLRWDT instruction 0 = By execution of the SLEEP instruction
bit 2	 Z: Zero bit 1 = The result of an arithmetic or logic operation is zero 0 = The result of an arithmetic or logic operation is not zero
bit 1	DC: Digit Carry/Borrow bit (for ADDWF and SUBWF instructions) ADDWF: 1 = A carry from the 4th low-order bit of the result occurred 0 = A carry from the 4th low-order bit of the result did not occur SUBWF: 1 = A borrow from the 4th low-order bit of the result did not occur 0 = A borrow from the 4th low-order bit of the result occurred
bit 0	C: Carry/Borrow bit (for ADDWF, SUBWF and RRF, RLF instructions) ADDWF: SUBWF: RRF or RLF: 1 = A carry occurred 1 = A borrow did not occur Load bit with LSb or MSb, respectively 0 = A carry did not occur 0 = A borrow occurred
Note 1:	Do not set both PA0 and PA1.

4.4 **OPTION Register**

The OPTION register is a 8-bit wide, write-only register, which contains various control bits to configure the Timer0/WDT prescaler and Timer0.

By executing the ${\tt OPTION}$ instruction, the contents of the W register will be transferred to the OPTION register. A Reset sets the OPTION<7:0> bits.

If the TOSC bit is set to '1', it will override the TRIS function on the T0CKI pin.

REGISTER 4-2: OPTION: OPTION REGISTER

W-1	W-1	W-1	W-1	W-1	W-1	W-1	W-1
GPWU	GPPU	T0CS	T0SE	PSA		PS<2:0>	
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	x = Bit is unknown
-n = Value at POR	'1' = Bit is set	'0' = Bit is cleared

bit 7	GPWU: Enable Wake-up On Pin Change bit
	1 = Disabled
	0 = Enabled
bit 6	GPPU: Enable Weak Pull-Ups bit
	1 = Disabled
	0 = Enabled
bit 5	T0CS: Timer0 Clock Source Select bit
	1 = Transition on T0CKI pin
	0 = Internal instruction cycle clock (CLKOUT)
bit 4	T0SE: Timer0 Source Edge Select bit
	1 = Increment on high-to-low transition on T0CKI pin0 = Increment on low-to-high transition on T0CKI pin

0 = Prescaler assigned to Timer0

PSA: Prescaler Assignment bit 1 = Prescaler assigned to the WDT

PS<2:0>: Prescaler Rate Select bits

bit 2-0

Bit Value	Timer0 Rate	WDT Rate
000	1:2	1:1
001	1:4	1:2
010	1:8	1:4
011	1:16	1:8
100	1:32	1:16
101	1:64	1:32
110	1 : 128	1:64
111	1:256	1 : 128

bit 3

4.5 OSCCAL Register

The Oscillator Calibration (OSCCAL) register is used to calibrate the 8 MHz internal oscillator macro. It contains seven bits of calibration that uses a two's complement scheme for controlling the oscillator speed. See Register 4-3 for details.

REGISTER 4-3: OSCCAL: OSCILLATOR CALIBRATION REGISTER

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	U-0
			CAL<6:0>				_
bit 7							bit 0

Legend:R = Readable bitW = Writable bitU = Unimplemented bit, read as '0'-n = Value at POR'1' = Bit is set'0' = Bit is clearedx = Bit is unknown

bit 7-1 **CAL<6:0>**: Oscillator Calibration bits

0111111 = Maximum frequency

.

.

0000001

0000000 = Center frequency

1111111

•

•

1000000 = Minimum frequency

bit 0 **Unimplemented**: Read as '0'

4.6 Program Counter

As a program instruction is executed, the Program Counter (PC) will contain the address of the next program instruction to be executed. The PC value is increased by one every instruction cycle, unless an instruction changes the PC.

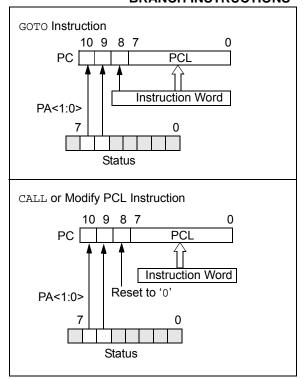
For a GOTO instruction, bits <8:0> of the PC are provided by the GOTO instruction word. The Program Counter (PCL) is mapped to PC<7:0>. Bits 5 and 6 of the STATUS register provide page information to bits 9 and 10 of the PC. (Figure 4-3).

For a CALL instruction, or any instruction where the PCL is the destination, bits <7:0> of the PC again are provided by the instruction word. However, PC<8> does not come from the instruction word, but is always cleared (Figure 4-3).

Instructions where the PCL is the destination, or modify PCL instructions, include MOVWF PCL, ADDWF PCL and BSF PCL, 5.

Note: Because PC<8> is cleared in the CALL instruction or any modify PCL instruction, all subroutine calls or computed jumps are limited to the first 256 locations of any program memory page (512 words long).

FIGURE 4-3: LOADING OF PC BRANCH INSTRUCTIONS



4.6.1 EFFECTS OF RESET

The PC is set upon a Reset, which means that the PC addresses the last location in the last page (i.e., the oscillator calibration instruction). After executing MOVLW XX, the PC will roll over to location 00h and begin executing user code.

The STATUS register page preselect bits are cleared upon a Reset, which means that page 0 is pre-selected.

Therefore, upon a Reset, a GOTO instruction will automatically cause the program to jump to page 0 until the value of the page bits is altered.

4.7 Stack

The PIC12F529T39A device has a four-deep, 12-bit wide hardware PUSH/POP stack.

A CALL instruction will PUSH the current value of Stack 1 into Stack 2 and then PUSH the current PC value, incremented by one, into Stack Level 1. If more than four sequential CALLs are executed, only the most recent four return addresses are stored.

A RETLW instruction will POP the contents of Stack Level 1 into the PC and then copy Stack Level 2 contents into Stack Level 1. If more than four sequential RETLWs are executed, the stack will be filled with the address previously stored in Stack Level 2. Note that the W register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

- **Note 1:** There are no Status bits to indicate Stack Overflow or Stack Underflow conditions.
 - 2: There are no instruction mnemonics called PUSH or POP. These are actions that occur from the execution of the CALL and RETLW instructions.

4.8 Indirect Data Addressing: INDF and FSR Registers

The INDF register is not a physical register. Addressing INDF actually addresses the register whose address is contained in the FSR register (FSR is a *pointer*). This is indirect addressing.

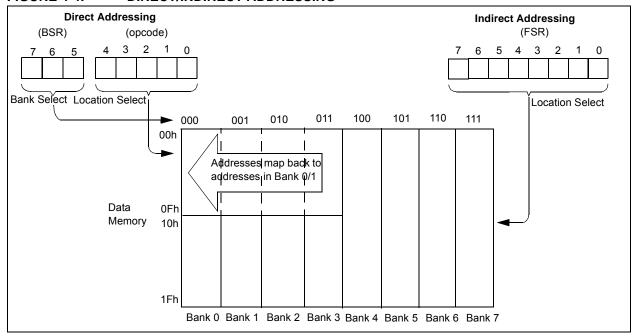
Reading INDF itself indirectly (FSR = 0) will produce 00h. Writing to the INDF register indirectly results in a no-operation (although Status bits may be affected).

The FSR is an 8-bit wide register. It is used in conjunction with the INDF register to indirectly address the data memory area.

EXAMPLE 4-1: HOW TO CLEAR RAM USING INDIRECT ADDRESSING

NEXT	MOVLW MOVWF CLRF	0x10 FSR INDF	;initialize pointer;to RAM;clear INDF
			;register
	INCF	FSR,F	;inc pointer
	BTFSC	FSR,4	;all done?
	GOTO	NEXT	;NO, clear next
CONTINUE			
	:		;YES, continue
	:		

FIGURE 4-4: DIRECT/INDIRECT ADDRESSING



4.9 Direct Data Addressing

Banking when using direct addressing methods is accomplished using the ${\tt MOVLB}$ instruction to write to the BSR. The BSR, like the OPTION register, is not mapped to user-accessible memory. The value in BSR has no effect on indirect addressed operations.

5.0 FLASH DATA MEMORY CONTROL

The Flash data memory is readable and writable during normal operation (full VDD range). This memory is not directly mapped in the register file space. Instead, it is indirectly addressed through the Special Function Registers (SFRs).

5.1 Reading Flash Data Memory

To read a Flash data memory location the user must:

- · Write the EEADR register
- · Set the RD bit of the EECON register

The value written to the EEADR register determines which Flash data memory location is read. Setting the RD bit of the EECON register initiates the read. Data from the Flash data memory read is available in the EEDATA register immediately. The EEDATA register will hold this value until another read is initiated or it is modified by a write operation. Program execution is suspended while the read cycle is in progress. Execution will continue with the instruction following the one that sets the WR bit. See Example 5-1 for sample code.

EXAMPLE 5-1: READING FROM FLASH DATA MEMORY

BANKSEL EEADR ;

MOVF DATA_EE_ADDR, W ;

MOVWF EEADR ;Data Memory ;Address to read BANKSEL EECON1 ;

BSF EECON, RD ;EE Read MOVF EEDATA, W ;W = EEDATA

Note: Only a BSF command will work to enable the Flash data memory read documented in Example 5-1. No other sequence of commands will work, no exceptions.

5.2 Writing and Erasing Flash Data Memory

Flash data memory is erased one row at a time and written one byte at a time. The 64-byte array is made up of eight rows. A row contains eight sequential bytes. Row boundaries exist every eight bytes.

Generally, the procedure to write a byte of data to Flash data memory is:

- Identify the row containing the address where the byte will be written.
- If there is other information in that row that must be saved, copy those bytes from Flash data memory to RAM.

- Perform a row erase of the row of interest.
- 4. Write the new byte of data and any saved bytes back to the appropriate addresses in Flash data memory.

To prevent accidental corruption of the Flash data memory, an unlock sequence is required to initiate a write or erase cycle. This sequence requires that the bit set instructions used to configure the EECON register happen exactly as shown in Example 5-2 and Example 5-3, depending on the operation requested.

5.2.1 ERASING FLASH DATA MEMORY

A row must be manually erased before writing new data. The following sequence must be performed for a single row erase.

- Load EEADR with an address in the row to be erased.
- Set the FREE bit to enable the erase.
- Set the WREN bit to enable write access to the array.
- 4. Set the WR bit to initiate the erase cycle.

If the WREN bit is not set in the instruction cycle after the FREE bit is set, the FREE bit will be cleared in hardware

If the WR bit is not set in the instruction cycle after the WREN bit is set, the WREN bit will be cleared in hardware.

Sample code that follows this procedure is included in Example 5-2.

Program execution is suspended while the erase cycle is in progress. Execution will continue with the instruction following the one that sets the WR bit.

EXAMPLE 5-2: ERASING A FLASH DATA MEMORY ROW

BANKSEL	EEADR	
MOVLW	EE_ADR_ERASE	; LOAD ADDRESS OF ROW TO
		; ERASE
MOVWF	EEADR	;
BSF	EECON, FREE	; SELECT ERASE
BSF	EECON, WREN	; ENABLE WRITES
BSF	EECON, WR	; INITITATE ERASE

Note 1: The FREE bit may be set by any command normally used by the core. However, the WREN and WR bits can only be set using a series of BSF commands, as documented in Example 5-1. No other sequence of commands will work, no exceptions.

2: Bits <5:3> of the EEADR register indicate which row is to be erased.

5.2.2 WRITING TO FLASH DATA MEMORY

Once a cell is erased, new data can be written. Program execution is suspended during the write cycle. The following sequence must be performed for a single byte write.

- Load EEADR with the address.
- 2. Load EEDATA with the data to write.
- Set the WREN bit to enable write access to the array.
- 4. Set the WR bit to initiate the erase cycle.

If the WR bit is not set in the instruction cycle after the WREN bit is set, the WREN bit will be cleared in hardware.

Sample code that follows this procedure is included in Example 5-3.

EXAMPLE 5-3: WRITING A FLASH DATA MEMORY ROW

BANKSEL	EEADR		
MOVLW	EE_ADR_WRITE	;	LOAD ADDRESS
MOVWF	EEADR	;	
MOVLW	EE_DATA_TO_WRITE	;	LOAD DATA
MOVWF	EEDATA	;	INTO EEDATA REGISTER
BSF	EECON, WREN	;	ENABLE WRITES
BSF	EECON, WR	;	INITITATE ERASE

- Note 1: Only a series of BSF commands will work to enable the memory write sequence documented in Example 5-2. No other sequence of commands will work, no exceptions.
 - 2: For reads, erases and writes to the Flash data memory, there is no need to insert a NOP into the user code as is done on mid-range devices. The instruction immediately following the "BSF EECON,WR/RD" will be fetched and executed properly.

5.3 Write Verify

Depending on the application, good programming practice may dictate that data written to the Flash data memory be verified. Example 5-4 is an example of a write verify.

EXAMPLE 5-4: WRITE VERIFY OF DATA EEPROM

```
; EEDATA has not changed
MOVF
        EEDATA, W
                      ;from previous write
BSF
        EECON, RD
                     ;Read the value written
XORWF
        EEDATA, W
                     ; Is data the same
BTFSS
        STATUS, Z
GOTO
        WRITE ERR
                     ;No, handle error
                     ¡Yes, continue
```

5.4 Code Protection

Code protection does not prevent the CPU from performing read or write operations on the Flash data memory. Refer to the code protection chapter for more information.

NOTES:

6.0 I/O PORT

As with any other register, the I/O register(s) can be written and read under program control. However, read instructions (e.g., MOVF PORTB, W) always read the I/O pins independent of the pin's Input/Output modes. On Reset, all I/O ports are defined as input (inputs are at high-impedance) since the I/O control registers are all set

6.1 **GPIO**

GPIO is an 8-bit I/O register. Only the low-order six bits are used (GP<5:0>). Bits 7 and 6 are unimplemented and read as '0's. Please note that GP3 is an input-only pin. The Configuration Word can set several I/O's to alternate functions. When acting as alternate functions, the pins will read as '0' during a port read. Pins GP0, GP1, and GP3 can be configured with weak pull-ups and also for wake-up on change. The wake-up on change and weak pull-up functions are not pin selectable. If GP3/MCLR is configured as MCLR, weak pull-up is always on and wake-up on change for this pin is not enabled.

6.2 TRIS Registers

The Output Driver Control registers are loaded with the contents of the W register by executing the TRIS f instruction. A '1' from a TRISGPIO register bit puts the corresponding output driver in a high-impedance (Input) mode. A '0' puts the contents of the output data latch on the selected pins, enabling the output buffer.

The TRISGPIO register is "write-only". Bits <5:0> are set (output drivers disabled) upon Reset.

Note:	If the TOCS bit is set to '1', it will override
	the TRISGPIO function on the TOCKI pin.

TABLE 6-1: WEAK PULL-UP ENABLED PINS

Pin	WPU	WU
GP0	Y	Υ
GP1	Y	Y
GP2	N	N
GP3	Y ⁽¹⁾	Y
GP4	N	N
GP5	N	N

Note 1: When MCLRE = 1, the weak pull-up on GP3/MCLR is always enabled.

2: WPU = Weak pull-up; WU = Wake-up.

REGISTER 6-1: GPIO: GPIO REGISTER

U-0	U-0	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x	R/W-x
_	_	GP5	GP4	GP3	GP2	GP1	GP0
bit 7							bit 0

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

bit 7-6 Unimplemented: Read as '0' bit 5-0 GP<5:0>: GPIO I/O Pin bits 1 = GPIO pin is >VIH min.

0 = GPIO pin is <VIL max.

REGISTER 6-2: TRISGPIO: TRI-STATE GPIO REGISTER

U-0	U-0	W-1	W-1	W-1	W-1	W-1	W-1
_	_	TRISGPI05	TRISGPIO4	TRISGPI03	TRISGPI02	TRISGPI01	TRISGPI00
bit 7							bit 0

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

bit 7-6 **Unimplemented:** Read as '0'

bit 5-0 TRISGPIO<5:0>: GPIO Tri-State Control bits

1 = GPIO pin configured as an input (tri-stated)

0 = GPIO pin configured as an output

6.3 I/O Interfacing

The equivalent circuit for an I/O port pin is shown in Figure 6-1. All port pins, except GP3 which is input only, may be used for both input and output operations. For input operations, these ports are non-latching. Any input must be present until read by an input instruction (e.g., MOVF GPIO, W). The outputs are latched and remain unchanged until the output latch is rewritten. To use a port pin as output, the corresponding direction control bit in TRISGPIO must be cleared (= 0). For use as an input, the corresponding TRISGPIO bit must be set. Any I/O pin (except GP3) can be programmed individually as input or output.

FIGURE 6-1: PIC12F529T39A EQUIVALENT CIRCUIT FOR I/O PINS - GP0/GP1 V_{DD} O Data Data Latch Pin WR Q Q WREG TRIS Latch Q TRIS 'F' RD Port D Wake-up on change Latch Pin Change **GP0/ICSPDAT GP1/ICSPCLK** · General purpose I/O · General purpose I/O In-Circuit Serial Programming[™] data In-circuit Serial Programming™ clock · Wake-up on input change trigger · Wake-up on input change trigger

FIGURE 6-2: GP2/TOCK1

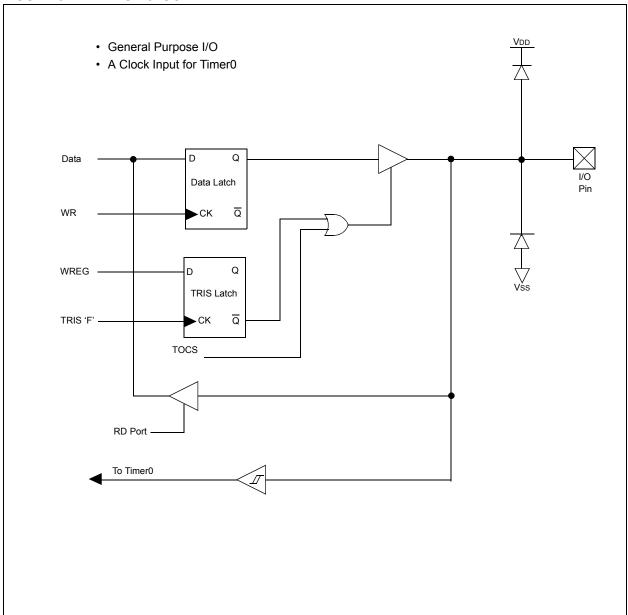


FIGURE 6-3: GP4/OSC2

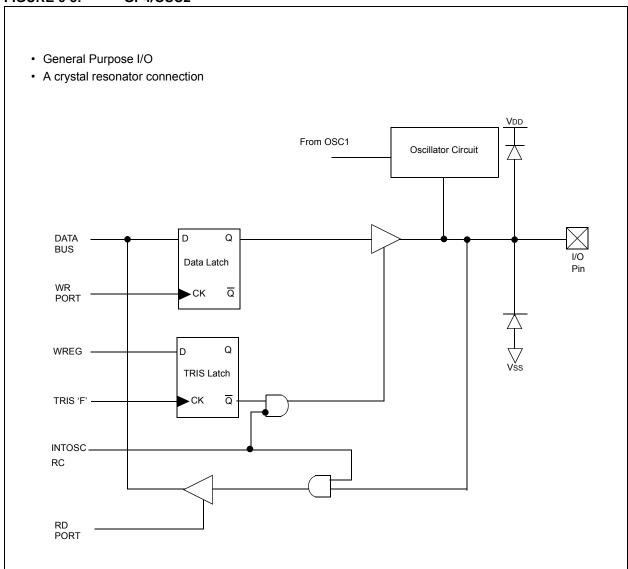


FIGURE 6-4: GP5/OSC1/CLKIN

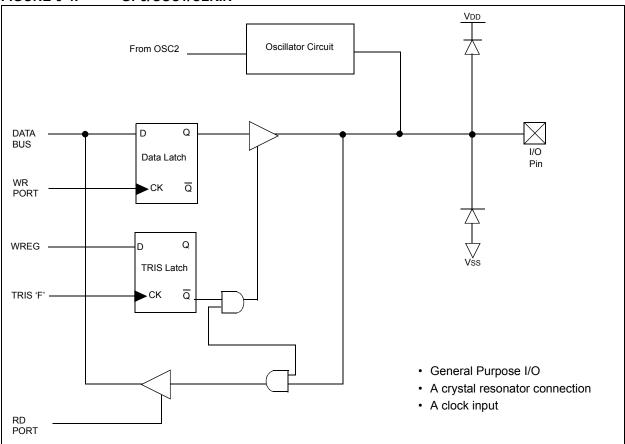


FIGURE 6-5: GP3 (WITH WEAK PULL-UP AND WAKE-UP ON CHANGE)

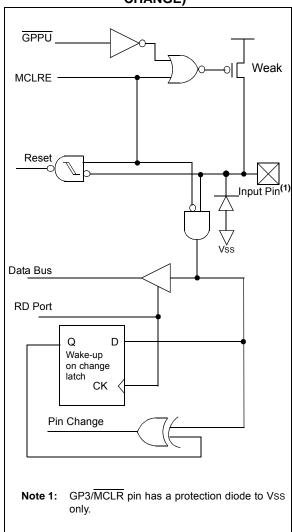


TABLE 6-2: SUMMARY OF PORT REGISTERS

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
GPIO	_	_	GP5	GP4	GP3	GP2	GP1	GP0	22
TRISGPIO	_	_	TRISGPI05	TRISGPIO4	TRISGPIO3	TRISGPI02	TRISGPI01	TRISGPI00	22
STATUS	GPWUF	PA1	PA0	TO	PD	Z	DC	С	13
OPTION	GPWU	GPPU	T0CS	T0SE	PSA	PS2	PS1	PS0	14

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0', Shaded cells = unimplemented, read as '0', q = depends on the condition

6.4 I/O Programming Considerations

6.4.1 BIDIRECTIONAL I/O PORTS

Some instructions operate internally as read followed by write operations. The BCF and BSF instructions, for example, read the entire port into the CPU, execute the bit operation and re-write the result. Caution must be used when these instructions are applied to a port where one or more pins are used as input/outputs. For example, a BSF operation on bit 5 of GPIO will cause all eight bits of GPIO to be read into the CPU, bit 5 to be set and the GPIO value to be written to the output latches. If another bit of GPIO is used as a bidirectional I/O pin (say bit 0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the Input mode, no problem occurs. However, if bit 0 is switched into Output mode later on, the content of the data latch may now be unknown.

Example 6-1 shows the effect of two sequential Read-Modify-Write instructions (e.g., BCF, BSF, etc.) on an I/O port.

A pin actively outputting a high or a low should not be driven from external devices at the same time in order to change the level on this pin ("wired OR", "wired AND"). The resulting high output currents may damage the chip.

EXAMPLE 6-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

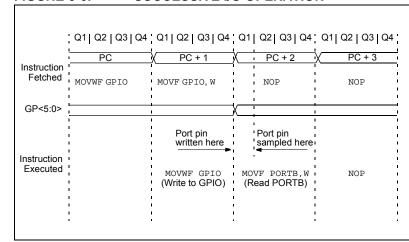
```
; Initial GPIO Settings
;GPIO<5:3> Inputs
;GPIO<2:0> Outputs
                   GPIO latch
                                 GPIO pins
                                  --11 pppp
 BCF
         GPIO, 5
                   ;--01 -ppp
                   ;--10 -ppp
                                  --11 pppp
 BCF
         GPIO, 4
        007h;
 MOVLW
 TRIS
        GPIO
                   ;--10 -ppp
                                  --11 pppp
Note 1:
         The user may have expected the pin values to
```

be '--00 $\,\mathrm{pppp}$ '. The 2nd BCF caused GP5 to be latched as the pin value (High).

6.4.2 SUCCESSIVE OPERATIONS ON I/O PORTS

The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 6-6). Therefore, care must be exercised if a write, followed by a read operation, is carried out on the same I/O port. The sequence of instructions should allow the pin voltage to stabilize (load dependent) before the next instruction causes that file to be read into the CPU. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a ${\tt NOP}$ or another instruction not accessing this I/O port.

FIGURE 6-6: SUCCESSIVE I/O OPERATION



This example shows a write to GPIO followed by a read from GPIO.

Data setup time = (0.25 Tcy - TpD)

where: Tcy = instruction cycle.

TPD = propagation delay

Therefore, at higher clock frequencies, a write followed by a read may be problematic.

7.0 TIMERO MODULE AND TMRO REGISTER

The Timer0 module has the following features:

- 8-bit timer/counter register, TMR0
- Readable and writable
- 8-bit software programmable prescaler
- · Internal or external clock select:
 - Edge select for external clock

Figure 7-1 is a simplified block diagram of the Timer0 module.

Timer mode is selected by clearing the TOCS bit (OPTION<5>). In Timer mode, the Timer0 module will increment every instruction cycle (without prescaler). If the TMR0 register is written, the increment is inhibited for the following two cycles (Figure 7-2 and Figure 7-3). The user can work around this by writing an adjusted value to the TMR0 register.

Counter mode is selected by setting the T0CS bit (OPTION<5>). In this mode, Timer0 will increment either on every rising or falling edge of pin T0CKI. The T0SE bit (OPTION<4>) determines the source edge. Clearing the T0SE bit selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 7.1 "Using Timer0 with an External Clock".

The prescaler may be used by either the Timer0 module or the Watchdog Timer, but not both. The prescaler assignment is controlled in software by the control bit, PSA (OPTION<3>). Clearing the PSA bit will assign the prescaler to Timer0. The prescaler is not readable or writable. When the prescaler is assigned to the Timer0 module, prescale values of 1:2, 1:4,..., 1:256 are selectable. Section 7.2 "Prescaler" details the operation of the prescaler.

A summary of registers associated with the Timer0 module is found in Table 7-1.

The Timer0 contained in the CPU core follows the standard baseline definition.

FIGURE 7-1: TIMERO BLOCK DIAGRAM

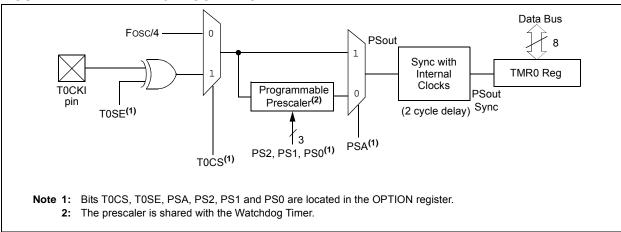


FIGURE 7-2: TIMERO TIMING: INTERNAL CLOCK/NO PRESCALE

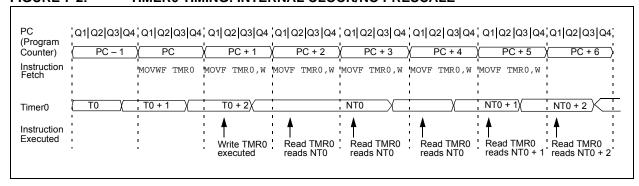


FIGURE 7-3: TIMERO TIMING: INTERNAL CLOCK/PRESCALE 1:2

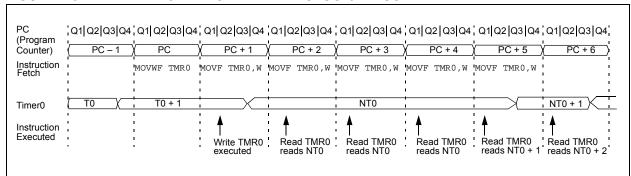


TABLE 7-1: REGISTERS ASSOCIATED WITH TIMER0

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
01h	TMR0	TMR0 Timer0 – 8-bit Real-Time Clock/Counter								29*
N/A	OPTION	GPWU	GPWU GPPU TOCS TOSE PSA PS2 PS1 PS0							14
N/A	TRIS	_	_	TRISGPI05	TRISGPI04	TRISGPI03	TRISGPI02	TRISGPI01	TRISGPI00	_

Legend:

x = unknown, u = unchanged, - = unimplemented, read as '0', Shaded cells = unimplemented, read as '0'.

7.1 Using Timer0 with an External Clock

When an external clock input is used for Timer0, it must meet certain requirements. The external clock requirement is due to internal phase clock (Tosc) synchronization. Also, there is a delay in the actual incrementing of Timer0 after synchronization.

7.1.1 EXTERNAL CLOCK SYNCHRONIZATION

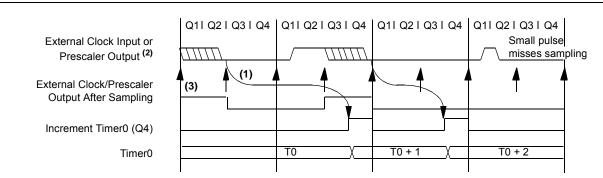
When no prescaler is used, the external clock input is the same as the prescaler output. The synchronization of T0CKI with the internal phase clocks is accomplished by sampling the prescaler output on the Q2 and Q4 cycles of the internal phase clocks (Figure 7-4). Therefore, it is necessary for T0CKI to be high for at least two Tosc (and a small RC delay of two Tt0H) and low for at least two Tosc (and a small RC delay of two Tt0H). Refer to the electrical specification of the desired device.

When a prescaler is used, the external clock input is divided by the asynchronous ripple counter-type prescaler, so that the prescaler output is symmetrical. For the external clock to meet the sampling requirement, the ripple counter must be taken into account. Therefore, it is necessary for TOCKI to have a period of at least four Tosc (and a small RC delay of four Tt0H) divided by the prescaler value. The only requirement on T0CKI high and low time is that they do not violate the minimum pulse width requirement of Tt0H. Refer to parameters 40, 41 and 42 in the electrical specification of the desired device.

7.1.2 TIMERO INCREMENT DELAY

Since the prescaler output is synchronized with the internal clocks, there is a small delay from the time the external clock edge occurs to the time the Timer0 module is actually incremented. Figure 7-4 shows the delay from the external clock edge to the timer incrementing.

FIGURE 7-4: TIMERO TIMING WITH EXTERNAL CLOCK



- Note 1: Delay from clock input change to Timer0 increment is 3 Tosc to 7 Tosc. (Duration of Q = Tosc). Therefore, the error in measuring the interval between two edges on Timer0 input = ±4 Tosc max.
 - 2: External clock if no prescaler selected; prescaler output otherwise.
 - 3: The arrows indicate the times at which sampling occurs.

7.2 Prescaler

An 8-bit counter is available as a prescaler for the Timer0 module or as a postscaler for the Watchdog Timer (WDT), respectively (see Section 8.6 "Watchdog Timer (WDT)"). For simplicity, this counter is being referred to as "prescaler" throughout this data sheet.

Note:

The prescaler may be used by either the Timer0 module or the WDT, but not both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT and vice versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio.

When assigned to the Timer0 module, all instructions writing to the TMR0 register (e.g., CLRF TMR0, MOVWF TMR0, etc.) will clear the prescaler. When assigned to WDT, a CLRWDT instruction will clear the prescaler along with the WDT. The prescaler is neither readable nor writable. On a Reset, the prescaler contains all '0's.

7.2.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control (i.e., it can be changed "on-the-fly" during program execution). To avoid an unintended device Reset, the following instruction sequence (Example 7-1) must be executed when changing the prescaler assignment from Timer0 to the WDT.

EXAMPLE 7-1: CHANGING PRESCALER (TIMER0 \rightarrow WDT)

CLRWDT ;Clear WDT

CLRF TMR0 ;Clear TMR0 and Prescaler

MOVLW b'00xx11111'

OPTION

CLRWDT ;PS<2:0> are 000 or 001

MOVLW b'00xx1xxx';Set Postscaler to

OPTION ;desired WDT rate

To change the prescaler from the WDT to the Timer0 module, use the sequence shown in Example 7-2. This sequence must be used even if the WDT is disabled. A CLRWDT instruction should be executed before switching the prescaler.

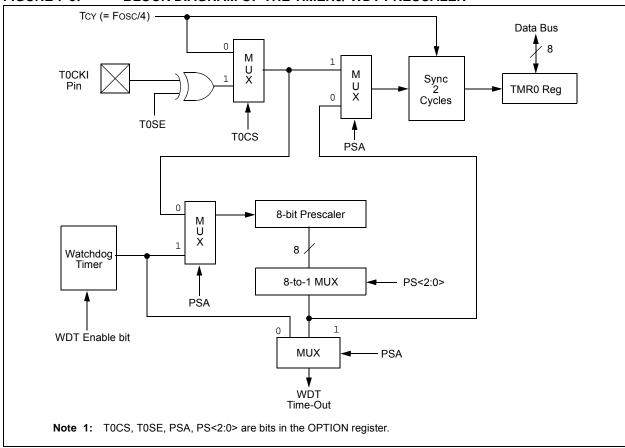
EXAMPLE 7-2: CHANGING PRESCALER (WDT \rightarrow TIMER0)

CLRWDT ;Clear WDT and ;prescaler

MOVLW b'xxxx0xxx';Select TMR0, new ;prescale value and ;clock source

OPTION

FIGURE 7-5: BLOCK DIAGRAM OF THE TIMERO/ WDT PRESCALER⁽¹⁾



8.0 SPECIAL FEATURES OF THE CPU

What sets a microcontroller apart from other processors are special circuits that deal with the needs of real-time applications. The PIC12F529T39A microcontroller has a host of such features intended to maximize system reliability, minimize cost through elimination of external components, provide power-saving operating modes and offer code protection. These features are:

- · Oscillator Selection
- · Reset:
 - Power-on Reset (POR)
 - Device Reset Timer (DRT)
 - Wake-up from Sleep on Pin Change
- Watchdog Timer (WDT)
- Sleep
- · Code Protection
- ID Locations
- In-Circuit Serial Programming™

The PIC12F529T39A device has a Watchdog Timer, which can be shut off only through Configuration bit WDTE. It runs off of its own RC oscillator for added reliability. If using XT or LP selectable oscillator options, there is always an 18 ms (nominal) delay provided by the Device Reset Timer (DRT), intended to keep the chip in Reset until the crystal oscillator is stable. If using INTRC or EXTRC, the DRT provides a 1 ms (nominal) delay.

The Sleep mode is designed to offer a very low-current Power-Down mode. The user can wake-up from Sleep through a change-on-input-pins or through a Watchdog Timer time-out. Several oscillator options are also made available to allow the part to fit the application, including an internal 4 MHz or 8 MHz oscillator. The EXTRC oscillator option saves system cost while the LP crystal option saves power. A set of Configuration bits are used to select various options.

8.1 Configuration Bits

The PIC12F529T39A Configuration Words consist of 12 bits. Configuration bits can be programmed to select various device configurations. Two bits are for the selection of the oscillator type; one bit is the Watchdog Timer enable bit, one bit is the MCLR enable bit and six bits are for code protection (Register 8-1).

REGISTER 8-1: CONFIG: CONFIGURATION WORD REGISTER⁽¹⁾

U-1	P-1	P-1	P-1	P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1	R/P-1
_	CP3	CP2	CP1	CP0	CPDF	IOSCFS	MCLRE	PARITY	WDTE	FOSC1	FOSC0
bit 11											bit 0

Legend:

R = Readable bit W = Writable bit U = Unimplemented bit, read as '0'

-n = Value at POR '1' = Bit is set '0' = Bit is cleared x = Bit is unknown

bit 11 **Unimplemented**: Read as '1'

bit 10-7 CP<3:0>: Enhanced Code Protect bits

1011 = Code protect disabled 0010 = Code protect enabled

All others = Memory access disabled⁽³⁾

bit 6 **CPDF:** Code Protection bit – Flash Data Memory

1 = Code protection off0 = Code protection on

bit 5 IOSCFS: Internal Oscillator Frequency Select bit

1 = 8 MHz INTOSC speed 0 = 4 MHz INTOSC speed

bit 4 MCLRE: Master Clear Enable bit

1 = $GP3/\overline{MCLR}$ pin functions as \overline{MCLR}

0 = GP3/MCLR pin functions as GP3, MCLR internally tied to VDD

bit 3 **PARITY:** Configuration Word Parity bit⁽⁴⁾

1 = Parity bit set

0 = Parity bit clear

bit 2 WDTE: Watchdog Timer Enable bit

1 = WDT enabled

0 = WDT disabled

bit 1-0 FOSC<1:0>: Oscillator Selection bits

00 = LP oscillator with 18 ms DRT⁽²⁾

01 = XT oscillator with 18 ms DRT(2)

10 = INTRC with 1 ms DRT(2)

11 = EXTRC with 1 ms DRT⁽²⁾

- **Note 1:** Refer to the "*PIC12F529T48A/T39A Memory Programming Specification*" (DS41619) to determine how to program/erase the Configuration Word.
 - 2: DRT length (18 ms or 1 ms) is a function of clock mode selection. It is the responsibility of the application designer to ensure the use of either 18 ms (nominal) DRT or the 1 ms (nominal) DRT will result in acceptable operation. Refer to Figure 12-1 for VDD rise time and stability requirements for this mode of operation.
 - 3: See Section 8.9 "Program Verification/Code Protection".
 - 4: Set or clear to create odd parity with Configuration Word excluding CP<3:0>.

8.2 Oscillator Configurations

8.2.1 OSCILLATOR TYPES

The PIC12F529T39A device can be operated in up to four different oscillator modes. The user can program using the Configuration bits (FOSC<1:0>), to select one of these modes:

LP: Low-Power CrystalXT: Crystal/Resonator

• INTRC: Internal 4 MHz or 8 MHz Oscillator

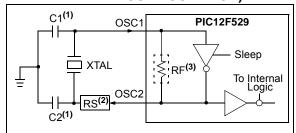
· EXTRC: External Resistor/Capacitor

8.2.2 CRYSTAL OSCILLATOR/CERAMIC RESONATORS

In XT or LP modes, a crystal or ceramic resonator is the (GP5)/OSC1/(CLKIN) connected to (GP4)/OSC2 pins to establish oscillation (Figure 8-1). The PIC12F529T39A oscillator designs require the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT or LP modes, the device can external clock source drive an (GP5)/OSC1/CLKIN pin (Figure 8-2). When the part is used in this manner, the output drive levels on the OSC2 pin are very weak. This pin should be left open and unloaded. Also when using this mode, the external clock should observe the frequency limits for the clock mode chosen (XT or LP).

Note 1: The user should verify that the device oscillator starts and performs as expected. Adjusting the loading capacitor values and/or the Oscillator mode may be required.

FIGURE 8-1: CRYSTAL OPERATION
(OR CERAMIC
RESONATOR)
(XT OR LP OSC
CONFIGURATION)



Note 1: See Capacitor Selection tables for recommended values of C1 and C2.

 A series resistor (RS) may be required for AT strip cut crystals.

3: RF approx. value = 10 M Ω .

FIGURE 8-2: EXTERNAL CLOCK INPUT OPERATION (XT OR LP OSC CONFIGURATION)

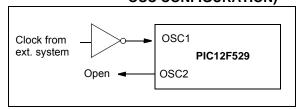


TABLE 8-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS

Osc Type	Resonator Freq.	Cap. Range C1	Cap. Range C2
XT	4.0 MHz	30 pF	30 pF
Note:	guidance or	nly. Since each aracteristics, the resonator ma values	e user should anufacturer for

TABLE 8-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR – PIC12F529T39A⁽²⁾

Osc	Resonator Freq.	Cap.Range	Cap. Range
Type		C1	C2
LP	32 kHz ⁽¹⁾	15 pF	15 pF
XT	200 kHz	47-68 pF	47-68 pF
	1 MHz	15 pF	15 pF
	4 MHz	15 pF	15 pF

Note 1: For VDD > 4.5V, C1 = C2 \approx 30 pF is recommended.

2: Component values shown are for design guidance only. Rs may be required to avoid overdriving crystals with low-drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

8.2.3 EXTERNAL CRYSTAL OSCILLATOR CIRCUIT

Either a pre-packaged oscillator or a simple oscillator circuit with TTL gates can be used as an external crystal oscillator circuit. Pre-packaged oscillators provide a wide operating range and better stability. A well-designed crystal oscillator will provide good performance with TTL gates. Two types of crystal oscillator circuits can be used: one with parallel resonance, or one with series resonance.

Figure 8-3 shows implementation of a parallel resonant oscillator circuit. The circuit is designed to use the fundamental frequency of the crystal. The 74AS04 inverter performs the 180-degree phase shift that a parallel oscillator requires. The 4.7 k Ω resistor provides the negative feedback for stability. The 10 k Ω potentiometers bias the 74AS04 in the linear region. This circuit could be used for external oscillator designs.

FIGURE 8-3: EXTERNAL PARALLEL RESONANT CRYSTAL OSCILLATOR CIRCUIT

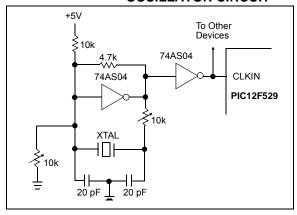
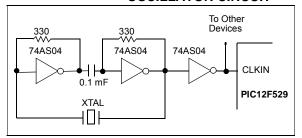


Figure 8-4 shows a series resonant oscillator circuit. This circuit is also designed to use the fundamental frequency of the crystal. The inverter performs a 180-degree phase shift in a series resonant oscillator circuit. The 330Ω resistors provide the negative feedback to bias the inverters in their linear region.

FIGURE 8-4: EXTERNAL SERIES
RESONANT CRYSTAL
OSCILLATOR CIRCUIT



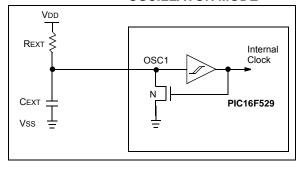
8.2.4 EXTERNAL RC OSCILLATOR

For timing insensitive applications, the RC circuit option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (REXT) and capacitor (CEXT) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit-to-unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low CEXT values. The user also needs to take into account variation due to tolerance of external R and C components used.

Figure 8-5 shows how the R/C combination is connected to the PIC12F529T39A device. For REXT values below 3.0 k Ω , the oscillator operation may become unstable, or stop completely. For very high REXT values (e.g., 1 M Ω), the oscillator becomes sensitive to noise, humidity and leakage. It is recommended keeping REXT between 5.0 k Ω and 100 k Ω .

Although the oscillator will operate with no external capacitor (CEXT = 0 pF), it is recommended using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance. See Figure 12-1 and Figure 12-2.

FIGURE 8-5: EXTERNAL RC OSCILLATOR MODE



8.2.5 INTERNAL 4/8 MHz RC OSCILLATOR

The internal RC oscillator provides a fixed 4/8 MHz (nominal) system clock at VDD = 3.5V and 25°C, (see **Section 12.0** "**Electrical Characteristics**" for information on variation over voltage and temperature).

In addition, a calibration instruction is programmed into the last address of memory, which contains the calibration value for the internal RC oscillator. This location is always non-code-protected, regardless of the code-protect settings. This value is programmed as a ${\tt MOVLW}\ XX$ instruction where XX is the calibration value, and is placed at the Reset vector. This will load the W register with the calibration value upon Reset and the PC will then roll over to the users program at address 0x000. The user then has the option of writing the value to the OSCCAL register (05h) or ignoring it.

OSCCAL, when written to with the calibration value, will "trim" the internal oscillator to remove process variation from the oscillator frequency.

Note:

Erasing the device will also erase the pre-programmed internal calibration value for the internal oscillator. The calibration value must be read prior to erasing the part so it can be reprogrammed correctly later.

For the PIC12F529T39A device, only bits <7:1> of OSCCAL are used for calibration. See Register 4-3 for more information.

Note: The bit 0 of the OSCCAL register is unimplemented and should be written as '0' when modifying OSCCAL for compatibility with future devices.

8.3 Reset

The device differentiates between various kinds of Reset:

- Power-on Reset (POR)
- MCLR Reset during normal operation
- MCLR Reset during Sleep
- · WDT Time-out Reset during normal operation
- · WDT Time-out Reset during Sleep
- · Wake-up from Sleep on pin change

Some registers are not reset in any way, and they are unknown on Power-on Reset (POR) and unchanged in any other Reset. Most other registers are reset to "Reset state" on Power-on Reset (POR), MCLR, WDT or Wake-up on pin change Reset during normal operation. They are not affected by a WDT Reset during Sleep or MCLR Reset during Sleep, since these Resets are viewed as resumption of normal operation.

TABLE 8-3: RESET CONDITIONS FOR REGISTERS

Register	Address	Power-on Reset	MCLR Reset, WDT Time-out, Wake-up On Pin Change				
W	_	qqqq qqq0(1)	qqqq qqq0 ⁽¹⁾				
INDF	00h	xxxx xxxx	uuuu uuuu				
TMR0	01h	xxxx xxxx	uuuu uuuu				
PCL	02h	1111 1111	1111 1111				
STATUS	03h	0001 1xxx	q00q quuu <mark>(2), (3)</mark>				
FSR	04h	110x xxxx	11uu uuuu				
OSCCAL	05h	1111 111-	uuuu uuu-				
PORTB	06h	xx xxxx	uu uuuu				
OPTION	_	1111 1111	1111 1111				
TRIS	_	11 1111	11 1111				
BSR	_	000	000				
EECON	21h	0 x000	0 q000				
EEDATA	25h	xxxx xxxx	uuuu uuuu				
EEADR	26h	xx xxxx	uu uuuu				

Legend: u = unchanged, x = unknown, - = unimplemented bit, read as '0', <math>q = value depends on condition.

- Note 1: Bits <7:1> of W register contain oscillator calibration values due to MOVLW XX instruction at top of memory.
 - 2: See Table 8-4 for Reset value for specific conditions.
 - 3: If Reset was due to wake-up on pin change, then bit 7 = 1. All other Resets will cause bit 7 = 0.

TABLE 8-4: RESET CONDITION FOR SPECIAL REGISTERS

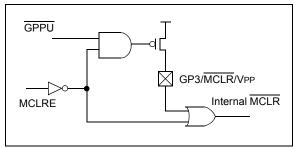
	STATUS Addr: 03h
Power-on Reset	0-01 1xxx
MCLR Reset during normal operation	0-0u uuuu
MCLR Reset during Sleep	0-01 0uuu
WDT Reset during Sleep	0-00 0uuu
WDT Reset normal operation	0-00 uuuu
Wake-up from Sleep on pin change	1-01 Ouuu

Legend: u = unchanged, x = unknown

8.3.1 MCLR ENABLE

This Configuration bit, when unprogrammed (left in the '1' state), enables the external MCLR function. When programmed, the MCLR function is tied to the internal VDD and the pin is assigned to be a I/O. See Figure 8-6.

FIGURE 8-6: MCLR SELECT



8.4 Power-on Reset (POR)

The PIC12F529T39A device incorporates an on-chip Power-on Reset (POR) circuitry, which provides an internal chip Reset for most power-up situations.

The on-chip POR circuit holds the chip in Reset until VDD has reached a high enough level for proper operation. To take advantage of the internal POR, program the GP3/MCLR/VPP pin as MCLR and tie through a resistor to VDD, or program the pin as GP3, in which case, an internal weak pull-up resistor is implemented using a transistor (refer to Table 12-4 for the pull-up resistor ranges). This will eliminate external RC components usually needed to create a Power-on Reset. A maximum rise time for VDD is specified. See Section 12.0 "Electrical Characteristics" for details.

When the devices start normal operation (exit the Reset condition), device operating parameters (voltage, frequency, temperature,...) must be met to ensure operation. If these conditions are not met, the devices must be held in Reset until the operating parameters are met.

A simplified block diagram of the on-chip Power-on Reset circuit is shown in Figure 8-7.

The Power-on Reset circuit and the Device Reset Timer (see **Section 8.5** "**Device Reset Timer (DRT)**") circuit are closely related. On power-up, the Reset latch is set and the DRT is <u>reset</u>. The DRT timer begins counting once it detects MCLR to be high. After the time-out period, which is typically 18 ms or 1 ms, it will reset the Reset latch and thus end the on-chip Reset signal.

A power-up example where \overline{MCLR} is held low is shown in Figure 8-8. VDD is allowed to rise and stabilize before bringing \overline{MCLR} high. The chip will actually come out of Reset TDRT after \overline{MCLR} goes high.

In Figure 8-9, the on-chip Power-on Reset feature is being used (MCLR and VDD are tied together or the pin is programmed to be GP3). The VDD is stable before the Start-up timer times out and there is no problem in getting a proper Reset. However, Figure 8-10 depicts a problem situation where VDD rises too slowly. The time between when the DRT senses that MCLR is high and when MCLR and VDD actually reach their full value, is too long. In this situation, when the start-up timer times out, VDD has not reached the VDD (min) value and the chip may not function correctly. For such situations, we recommend that external RC circuits be used to achieve longer POR delay times (Figure 8-9).

Note: When the devices start normal operation (exit the Reset condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in Reset until the operating conditions are met.

For additional information, refer to Application Note AN522, "Power-Up Considerations" (DS00522).

FIGURE 8-7: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT

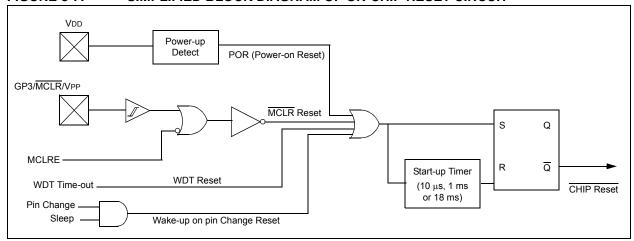


FIGURE 8-8: TIME-OUT SEQUENCE ON POWER-UP (MCLR PULLED LOW)

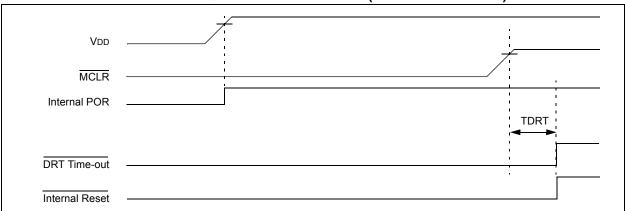
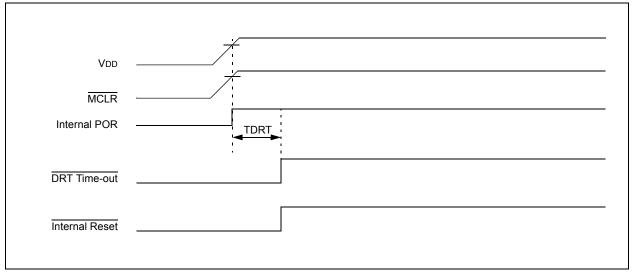
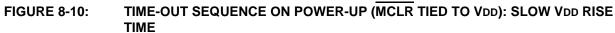
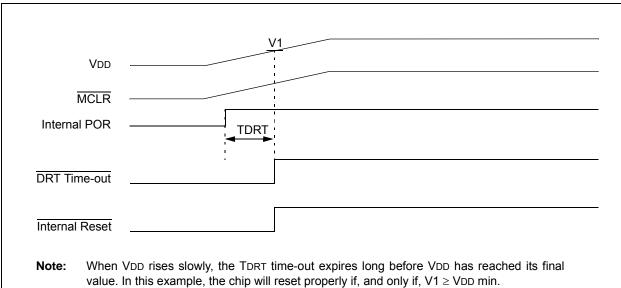


FIGURE 8-9: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME







8.5 Device Reset Timer (DRT)

On the PIC12F529T39A device, the DRT runs any time the device is powered up. DRT runs from Reset and varies based on oscillator selection and Reset type (see Table 8-5).

The DRT operates on an internal RC oscillator. The processor is kept in Reset as long as the DRT is active. The DRT delay allows VDD to rise above VDD min. and for the oscillator to stabilize.

Oscillator circuits based on crystals or ceramic resonators require a certain time after power-up to establish a stable oscillation. The on-chip DRT keeps the devices in a Reset condition after MCLR has reached a logic high (VIH MCLR) level. Programming GP3/MCLR/VPP as MCLR and using an external RC network connected to the MCLR input is not required in most cases. This allows savings in cost-sensitive and/or space restricted applications, as well as allowing the use of the GP3/MCLR/VPP pin as a general purpose input.

The Device Reset Time delays will vary from chip-to-chip due to VDD, temperature and process variation. See AC parameters for details.

The DRT will also be triggered upon a Watchdog Timer time-out from Sleep. This is particularly important for applications using the WDT to wake from Sleep mode automatically.

Reset sources are POR, MCLR, WDT time-out and wake-up on pin change. See Section 8.8.2 "Wake-up from Sleep", Notes 1, 2 and 3.

TABLE 8-5: DRT (DEVICE RESET TIMER PERIOD)

Oscillator Configuration	POR Reset	Subsequent Resets									
INTOSC, EXTRC	1 ms (typical)	10 μs (typical)									
LP, XT	18 ms (typical)	18 ms (typical)									

8.6 Watchdog Timer (WDT)

The Watchdog Timer (WDT) is a free running on-chip RC oscillator, which does not require any external components. This RC oscillator is separate from the external RC oscillator of the (GP5)/OSC1/CLKIN pin and the internal 4 or 8 MHz oscillator. This means that the WDT will run even if the main processor clock has been stopped, for example, by execution of a SLEEP instruction. During normal operation or Sleep, a WDT Reset or wake-up Reset, generates a device Reset.

The $\overline{\text{TO}}$ bit (STATUS<4>) will be cleared upon a Watchdog Timer Reset.

The WDT can be permanently disabled by programming the configuration WDTE as a '0' (see Section 8.1 "Configuration Bits"). Refer to the PIC12F529T39A Programming Specification (DS41316) to determine how to access the Configuration Word.

8.6.1 WDT PERIOD

The WDT has a nominal time-out period of 18 ms, (with no prescaler). If a longer time-out period is desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT (under software control) by writing to the OPTION register. Thus, a time-out period of a nominal 2.3 seconds can be realized. These periods vary with temperature, VDD and part-to-part process variations (see DC specs).

Under worst-case conditions (VDD = Min., Temperature = Max., max. WDT prescaler), it may take several seconds before a WDT time-out occurs.

8.6.2 WDT PROGRAMMING CONSIDERATIONS

The CLRWDT instruction clears the WDT and the postscaler, if assigned to the WDT, and prevents it from timing out and generating a device Reset.

The SLEEP instruction resets the WDT and the postscaler, if assigned to the WDT. This gives the maximum Sleep time before a WDT wake-up Reset.

FIGURE 8-11: WATCHDOG TIMER BLOCK DIAGRAM

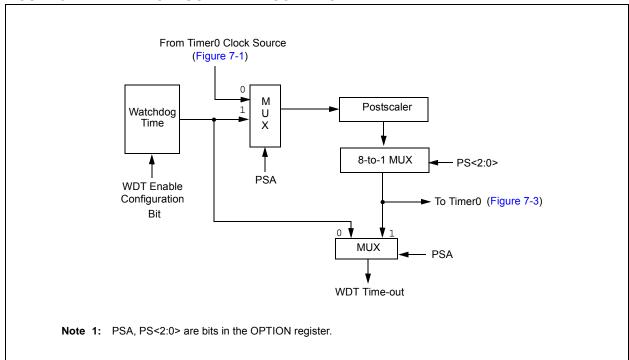


TABLE 8-6: SUMMARY OF REGISTER ASSOCIATED WITH THE WATCHDOG TIMER

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
OPTION	GPWU	GPPU	T0CS	T0SE	PSA	PS2	PS1	PS0	14

Legend: Shaded boxes = Not used by Watchdog Timer.

8.7 Time-out Sequence, Power-down and Wake-up from Sleep Status Bits (TO, PD, GPWUF)

The $\overline{\text{TO}}$, $\overline{\text{PD}}$ and (GPWUF) bits in the STATUS register can be tested to determine if a Reset condition has been caused by a power-up condition, a $\overline{\text{MCLR}}$ or Watchdog Timer (WDT) Reset.

TABLE 8-7: TO/PD/(GPWUF) STATUS
AFTER RESET

GPWUF	то	PD	Reset Caused By
0	0	0	WDT wake-up from Sleep
0	0	u	WDT time-out (not from Sleep)
0	1	0	MCLR wake-up from Sleep
0	1	1	Power-up
0	u	u	MCLR not during Sleep
1	1	0	Wake-up from Sleep on pin change

Legend: u = unchanged

Note 1: The TO, PD and GPWUF bits maintain their status (u) until a Reset occurs. A low-pulse on the MCLR input does not change the TO, PD and GPWUF Status bits

8.8 Power-down Mode (Sleep)

A device may be powered down (Sleep) and later powered up (wake-up from Sleep).

8.8.1 SLEEP

The Power-Down mode is entered by executing a SLEEP instruction.

If enabled, the Watchdog Timer will be cleared but keeps running, the $\overline{\text{TO}}$ bit (STATUS<4>) is set, the $\overline{\text{PD}}$ bit (STATUS<3>) is cleared and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, driving low or high-impedance).

Note: A Reset generated by a WDT time-out does not drive the MCLR pin low.

For lowest current consumption while powered down, the TOCKI input should be at VDD or Vss and the $GP3/\overline{MCLR}/VPP$ pin must be at a logic high level if \overline{MCLR} is enabled.

8.8.2 WAKE-UP FROM SLEEP

The device can wake-up from Sleep through one of the following events:

- An external Reset input on GP3/MCLR/VPP pin, when configured as MCLR.
- A Watchdog Timer Time-out Reset (if WDT was enabled).
- 7. A change on input pin GP0, GP1 and GP3 when wake-up on change is enabled.

These events cause a device Reset. The $\overline{\text{TO}}$, $\overline{\text{PD}}$ and GPWUF bits can be used to determine the cause of device Reset. The $\overline{\text{TO}}$ bit is cleared if a WDT time-out occurred (and caused wake-up). The $\overline{\text{PD}}$ bit, which is set on power-up, is cleared when SLEEP is invoked. The GPWUF bit indicates a change in state while in Sleep at pins GP0, GP1 and GP3 (since the last file or bit operation on GPIO port).

Note: Caution: Right before entering Sleep, read the input pins. When in Sleep, wake-up occurs when the values at the pins change from the state they were in at the last reading. If a wake-up on change occurs and the pins are not read before re-entering Sleep, a wake-up will occur immediately even if no pins change while in Sleep mode.

The WDT is cleared when the device wakes from Sleep, regardless of the wake-up source.

8.9 Program Verification/Code Protection

Code protection is enabled or disabled by writing the correct value to the CP<3:0> bits of the Configuration register. These bits must be written every time the device is erased.

If the code protection bits have not been enabled, the on-chip program and data memory can be read out for verification purposes.

The last location (the oscillator calibration value) can be read, regardless of the setting of the program memory's code protection bit. If the code-protect bit specific to the Flash data memory is programmed, then none of the contents of this memory region can be verified externally.

Refer to *PIC12F529T48A/T39A Memory Programming Specification* (DS41619) for more information on programming the Configuration Word.

Note: The device code protection must be disabled before attempting to program Flash memory.

8.10 ID Locations

Four memory locations are designated as ID locations where users can store checksum or other code identification numbers. These locations are not accessible during normal execution, but are readable and writable during program/verify.

Use only the lower four bits of the ID locations. The upper bits should be programmed as '0's.

8.11 In-Circuit Serial Programming™

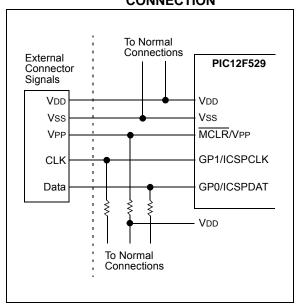
The PIC12F529T39A device can be serially programmed while in the end application circuit. This is simply done with two lines for clock and data, and three other lines for power, ground and the programming voltage. This allows users to manufacture boards with unprogrammed PIC12F519 device and then program the PIC12F519 device just before shipping the product. This also allows the most recent firmware, or a custom firmware, to be programmed.

The PIC12F529T39A device is placed into a Program/Verify mode by holding the GP1 and GP0 pins low while raising the $\overline{\text{MCLR}}$ (VPP) pin from VIL to VIHH (see programming specification). The GP1 pin becomes the programming clock, and the GP0 pin becomes the programming data. Both GP1 and GP0 pins are Schmitt Trigger inputs in this mode.

After Reset, a 6-bit command is then supplied to the device. Depending on the command, 14 bits of program data are then supplied to or from the device, depending if the command was a Load or a Read. For complete details of serial programming, please refer to the "PIC12F529T48A/T39A Memory Programming Specification," (DS41619).

A typical In-Circuit Serial Programming connection is shown in Figure 8-12.

FIGURE 8-12: TYPICAL IN-CIRCUIT
SERIAL PROGRAMMING
CONNECTION



9.0 RF TRANSMITTER

The RF transmitter is an ultra low-power, integrated multi-band Sub-GHz transmitter. It is capable of operating in the 310, 433, 868, and 915 MHz license-free frequency bands using Frequency Shift Keying (FSK) or On-Off Keying (OOK) modulation of an input data stream.

9.1 Circuit Description

The RF transmitter block diagram is shown in Figure 9-1 and the I/O pin definitions are shown in Table 9-1.

FIGURE 9-1: RF TRANSMITTER BLOCK DIAGRAM

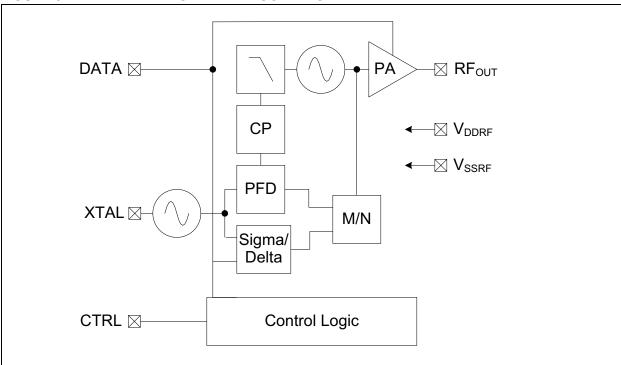


TABLE 9-1: RF TRANSMITTER PIN DESCRIPTION

Name	Function	Input Type	Output Type	Description
VDDRF	VDDRF	Power	_	RF Power Supply
CTRL	CTRL	CMOS	_	Configuration Selection and Configuration Clock
RFOUT	RFout	_	RF	Transmitter RF output
Vssrf	Vssrf	Power	_	RF Power Supply
DATA	DATA	CMOS	CMOS	Configuration Data and Transmit Data
XTAL	XTAL	XTAL	1	Crystal Oscillator

Note: The RF transmitter pins are independent from the microcontroller pins.

The RF transmitter contains of a sigma-delta fractional-N Phase-Locked Loop (PLL) frequency synthesizer. Frequency Shift Keying (FSK) modulation is made inside the PLL bandwidth. On-Off Keying (OOK) modulation is made by turning on and off the Power Amplifier (PA).

The reference frequency is generated by an internal crystal oscillator. An external quartz crystal resonator is connected to the XTAL pin and Ground (VSSRF). The choice of crystal frequency depends on the frequency band of choice.

The RF transmitter can deliver 0 dBm or +10 dBm into a 50Ω load via the RFouT pin. An external matching network is required for each power setting and frequency band for the best efficiency to the antenna.

9.2 Configuring the RF Transmitter

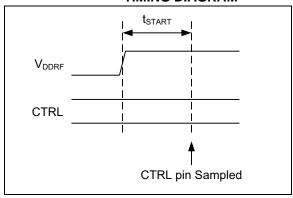
The CTRL and DATA pins are used to configure the RF transmitter for transmit frequency, output power, modulation, FSK frequency deviation, and sleep time. Once configured, the DATA pin is used to encode transmit data.

9.2.1 POWER-ON RESET (POR)

At power-on, the CTRL pin is sampled as shown in Figure 9-2 and depending on the CTRL pin logic level, the RF transmitter will enter one of two Power-on Reset (POR) values as shown in Table 9-3 and Table 9-4. To continue using the RF transmitter with these POR values, maintain the CTRL pin stable and at the powered-on logic level. With the DATA pin at logic '0', the RF transmitter will enter Sleep mode.

Note: It is recommended that a weak pull-up or pull-down resistor be placed on the CTRL pin to ensure the desired preset mode is selected at power-on.

FIGURE 9-2: MODE SELECTION TIMING DIAGRAM



If the POR settings are satisfactory for the application, a microcontroller output pin can be freed by placing a weak pull-up or pull-down resistor on the CTRL pin. Only the DATA pin needs to be connected to an I/O pin.

9.2.2 RF TRANSMITTER REGISTERS

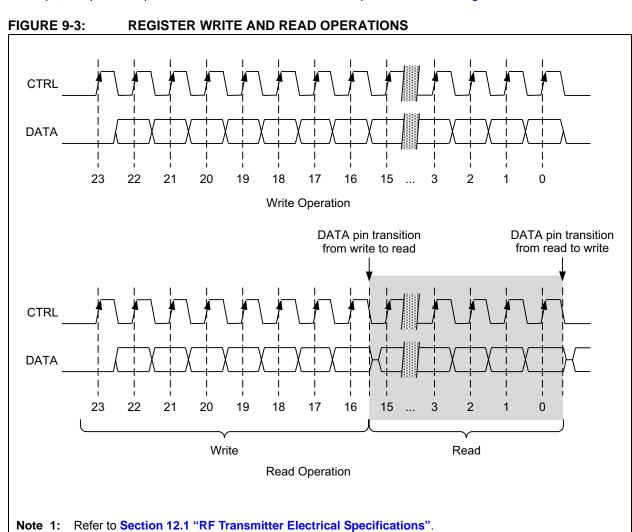
RF transmitter has three registers: Application, Frequency, and Status. These are used to write and read configuration parameters related to transmit frequency, output power, modulation, FSK frequency deviation, and Sleep time. A summary of register values are shown in Table 9-2. A detailed explanation of Application register is shown in Table 9-3, Frequency register values in Table 9-4, and STATUS register in Table 9-5.

To access the registers, the DATA line is sampled at each low-to-high transition on the CTRL pin. A total of 24 transitions are required on the CTRL pin to successfully write or read a value in the registers. Register write and read operations are shown in Figure 9-3.

Writing and reading the RF transmitter registers should be done when the device is in Sleep mode. See Section 9.2.4 "Sleep Mode".

In the event that spurious activity (for example MCU interrupt or Reset) or less than 24 clock cycles on the CTRL pin, a special sequence over the CTRL and

DATA pins can be used to recover serial communications with the RF transmitter. The recover sequence is shown in Figure 9-4.



Exactly 24 clock cycles are required for proper configuration.

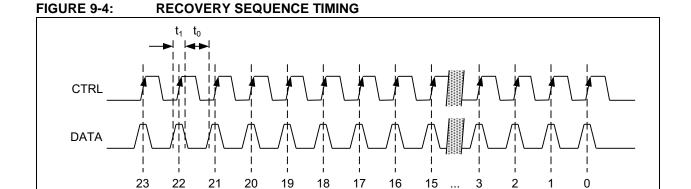


TABLE 9-2: RF TRANSMITTER REGISTER SUMMARY

23	22	21	20	19	18	17	16	15 14 13 12 11 10 9 8 7 6 5 4 3 2 1 0 Instruction																						
0	0	0	0	0	0	0	0		DA<15:0>									Write	1 P P											
0	0	1	1	0	0	1	1							I	DA	\<1	5:0	>								Read Register (see Table 9-3)				
0	0	0	1	1					DF<18:0>									Write	Frequency											
0	1	0	0	0	1	0	0		DF<15:0>								Read	Register (see Table 9-4)												
0	1	0	1	0	1	0	1)V<7	':0>						D	S<	4:0)>	DI	- <1	8:1	6>	Read	STATUS Register (see Table 9-5)			

TABLE 9-3: APPLICATION REGISTER

Bit	Name	Value	Sattin a	Power-c	n Reset	Notes							
DIT	Name	value	Setting	CTRL = 0	CTRL = 1	Notes							
DA15	Mode	0	Automatic	0	0	Refer to Section 9.2.5 "Manual							
		1	Manual			Transmit Mode".							
DA14	Modulation	0	FSK	0	1	Refer to Section 9.3 "Modulation							
		1	OOK			Selection".							
DA13	Band	0	310-450 MHz	1	0	Refer to Section 9.4 "Frequency							
		1	860-870 MHz 902-928 MHz			Selection and Configuration".							
DA<12:5>	Frequency Deviation (f _{DEV})	_	_	_	0x06 ⁽¹⁾	FSK mode only. Refer to Section 9.4.3 "Frequency Calculation".							
DA4	Output Power	0	0 dBm	1	1								
		1	10 dBm										
DA3	Transmitter Off	0	2 ms	1	0	_							
	Time (t _{OFFT})	1	20 ms										
DA<2:0>	Reserved	100(2)	_	100	100	_							

Note 1: Actual frequency deviation value dependant on crystal frequency.

2: When writing to the Application register, DA<2:0> must be 0b100.

TABLE 9-4: FREQUENCY REGISTER

Bit	Nama	Value	Catting	Power-o	n Reset	Notes		
Bit	Name	value	Setting	CTRL = 0	CTRL = 1			
DF<18:0>	Transmit Frequency (f _{TX})	_	_	0x42C1C ⁽¹⁾	0x42CAD ⁽¹⁾	Refer to Section 9.4 "Frequency Selection and Configuration". When reading frequency, the Most Significant 3 bits are read from the STATUS register (see Table 9-5)		

Note 1: Actual frequency value dependant on crystal frequency.

9.2.3 DATA TRANSMISSION

TABLE 9-5: STATUS REGISTER

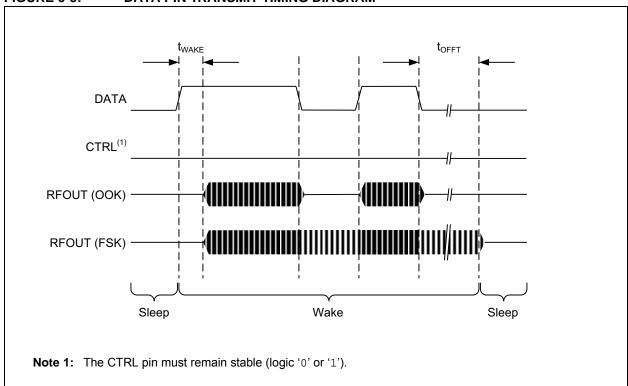
Bit	Name	Value	Cotting	Power-c	n Reset	Notes	
DIL	Name	value	Setting	CTRL = 0	CTRL = 1		
DV<7:0>	Chip Version	0x11	_	0x11	0x11	0x11 = Version A1	
DS<4:2>	Reserved	_	_	_	_	_	
DS1	TX Ready	0	Sleep	_	_		
		1	Transmitting	_	_		
DS0	Reserved	_	_	_	_		
DF<18:16>	Transmit Frequency (f _{TX})	_	_	0b100	0b100	Refer to Section 9.4 "Frequency Selection and Configuration". When reading frequency, the Most Significant 3 bits are read from the STATUS register (see Table 9-5)	

RF data is transmitted when the DATA pin is at a logic '1' for greater than t_{WAKE} as shown in Figure 9-5. The CTRL pin must remain stable (either logic '0' or '1'). If the modulation mode is OOK, the transmitted signal is turned on and off by the DATA pin. If the modulation mode is FSK, the transmitted signal is frequency shifted by the DATA pin. The encoding of the transmitted signal is determined by the length of time the DATA pin is held logic '0' or '1'.

9.2.4 SLEEP MODE

The RF transmitter will automatically enter Sleep mode when the DATA pin is a logic '0' for greater than t_{OFFT} , as shown in Figure 9-5. t_{OFFT} can be configured for 2 or 20 ms in the Application register (see Table 9-3).

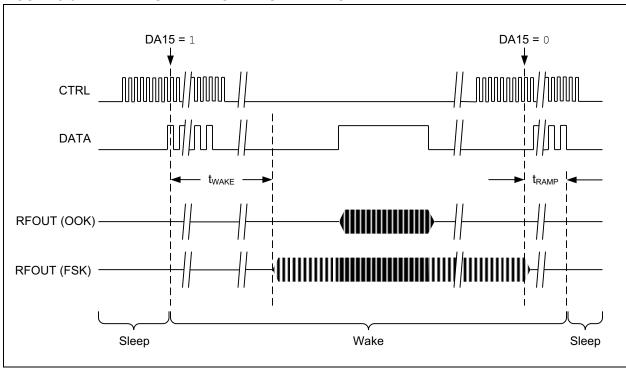
FIGURE 9-5: DATA PIN TRANSMIT TIMING DIAGRAM



9.2.5 MANUAL TRANSMIT MODE

The RF transmitter can continuously transmit by setting the mode bit (DA15) to a logic '1' in the Applications register (see Table 9-3). It will continuously transmit RF data presented on the DATA pin without automatically entering Sleep mode. To cease transmission the mode bit is must be cleared (DA15 = 0). Figure 9-6 shows the Manual Transmit mode timing.

FIGURE 9-6: MANUAL TRANSMIT MODE TIMING



9.3 Modulation Selection

9.3.1 ON-OFF KEYING (OOK)

OOK modulation can be configured by setting the modulation DA14 bit in the Application register (Table 9-3). Data is transmitted as stated in **Section 9.2.3 "Data Transmission"**.

9.3.2 FREQUENCY SHIFT KEYING (FSK)

FSK modulation can be configured by clearing the modulation DA14 bit in the Application register. Frequency Deviation (f_{DEV}) is configured by setting the DA<12:5> bits in the Application register. Data is transmitted as stated in Section 9.2.3 "Data Transmission".

9.3.3 DIGITAL TRANSMISSION SYSTEM (DTS)

In the United States and Canada, digital modulation techniques are permitted (FCC Part 15.247 and RSS-210, respectively). The RF transmitter can be configured for DTS mode by selecting FSK and f_{DEV} = 200 kHz. Data encoding techniques, such as data whitening, may be needed to ensure that the minimum 6 dB bandwidth is at least 500 kHz.

9.4 Frequency Selection and Configuration

The RF transmitter is capable of generating many of the popular RF frequencies that are permitted within the radio regulations of the country the finished product will be sold. The RF frequency configuration is performed by determining which frequency band, selecting the crystal frequency, and setting the frequency value in the Frequency register DF<18:0>. If FSK modulation is used, the frequency deviation is set in the Application register DA<12:5>. See Section 9.2.2 "RF Transmitter Registers" for information on Configuration register settings.

9.4.1 BAND SELECTION

The Band bit, DA13, in the Application register configures the RF transmitter for a range of frequencies for a given crystal frequency as shown in Table 9-6.

TABLE 9-6: FREQUENCY BAND SELECTION

Band Setting DA<13>	Frequency Band (f _{RF})	Crystal Frequency (f _{XTAL})				
0	310 -450 MHz	22 MHz				
	312 -450 MHz	24 MHz				
	338-450 MHz	26 MHz				
1	863-870 MHz	22 MHz				
	902-924 MHz	22 IVITZ				
	863-870 MHz	24 MHz				
	902-928 MHz	26 MHz				

9.4.2 CRYSTAL SELECTION

Once the frequency band has been selected, the choice of crystal frequency is flexible provided the crystal meets the specifications summarized in Table 9-7, the boundaries of the Frequency register DF<18:0> are followed as shown in Figure 9-7, and RF transmit frequency error is acceptable (see Section 9.4.3 "Frequency Calculation").

TABLE 9-7: CRYSTAL RESONATOR SPECIFICATIONS

Symbol	Description	Min.	Тур.	Max.	Unit
FXTAL	Crystal Frequency	22	_	26	MHz
CL	Load Capacitance	_	15	_	pF
ESR	Equivalent Series Resistance	_	_	100	Ohms

The crystal frequency tolerance and frequency stability over the operating temperature range depends on the system frequency budget. Typically, the receiver crystal frequency tolerance, stability, and receiver bandwidth will have the greatest influence. For OOK modulation, the transmitted RF signal (f_{RF}) should remain inside the receiver bandwidth, otherwise signal degradation will occur. For FSK modulation, f_{RF} should remain inside the receiver bandwidth and within 0.5 * f_{DEV} .

As a general practice, do not choose a RF transmit signal (f_{RF}) with an integer or near integer multiple of f_{XTAL} . This will result in higher noise and spurious emissions.

9.4.3 FREQUENCY CALCULATION

Once the frequency band and crystal frequency are selected, the RF transmit signal ($f_{\rm RF}$) is calculated by setting the Frequency register DF(18:0) bits according to the formula shown in Figure 9-7. If the calculated value for DF(18:0) is not an integer, there will be an associated transmit frequency error. Ensure that this error is within the acceptable system frequency budget. Similarly, the frequency deviation is calculated as shown in Figure 9-7.

FIGURE 9-7: FREQUENCY CALCULATION

Band 0

$$DF(18:0) = \frac{f_{RF} * 16384}{f_{XTAI}}$$

212992 < DF(18:0) < 344064

Note: Check f_{RF} frequency error by calculating f_{RF} with integer value of DF(18:0).

$$DA(12:5) = \frac{f_{DEV} * 16384}{f_{XTAL}}$$

 $10 \text{ kHz} \le f_{DEV} \le 200 \text{ kHz}$

Note: Check f_{DEV} frequency error by calculating f_{DEV} with integer value of DA(12:5).

Band 1

$$DF(18:0) = \frac{f_{RF} * 8192}{f_{XTAI}}$$

212992 < DF(18:0) < 344064

Note: Check f_{RF} frequency error by calculating f_{RF} with integer value of DF(18:0).

$$DA(12:5) = \frac{f_{DEV} * 8192}{f_{XTAL}}$$

 $10 \text{ kHz} \le f_{DEV} \le 200 \text{ kHz}$

Note: Check f_{DEV} frequency error by calculating f_{DEV} with integer value of DA(12:5).

 f_{RF} and f_{XTAL} values in the range shown in Table 9-6

9.5 Applications

9.5.1 SOFTWARE INITIALIZATION

EXAMPLE 9-1: SAMPLE INITIALIZATION CODE

```
#define APP_REG_PREFIX 0
#define FREQ_REG_PREFIX 0x18
void sendTxCommand(unsigned char cmd)
    // The `T39A samples data on the rising edge of clock. Clock is idle low.
    unsigned char i;
    for (i=0; i<8; i++)
    {
          if (cmd & 0x80)
              DATA\_OUT = 1;
          else
              DATA_OUT = 0;
          CTRL_OUT = 1;
          NOP();
          NOP();
          CTRL_OUT = 0;
          cmd = cmd << 1;
void TX_Init(void)
    unsigned char app_high = (T39A_APP_CONFIG & 0x00FF00) >> 8;
    unsigned char app_low = (T39A_APP_CONFIG & 0x0000FF);
    unsigned char f_upper = (T39A_FREQ_CONFIG & 0x70000) >> 16;
    unsigned char f_high = (T39A_FREQ_CONFIG \& 0x0FF00) >> 8;
    unsigned char f_low = (T39A_FREQ_CONFIG \& 0x000FF);
    sendTxCommand(APP_REG_PREFIX);
    sendTxCommand(app_high);
    sendTxCommand(app_low);
    sendTxCommand(FREQ_REG_PREFIX | f_upper);
    sendTxCommand(f_high);
    sendTxCommand(f_low);
    return;
```

9.5.2 APPLICATION CIRCUIT

Figure 9-8 describes a sample four-button remote transmitter application schematic. Table 9-8 contains its bill of materials. This schematic and bill of materials is a design suggestion only. Actual component values will be dependent on implementation parameters.

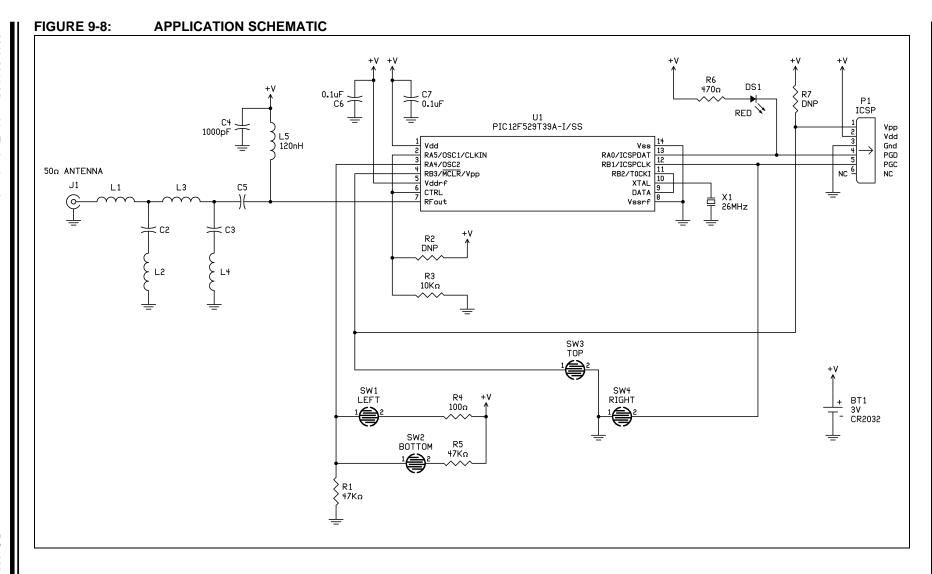


TABLE 9-8: BILL OF MATERIALS

	Danimata	Walara	Description.			
	Designator	Value	Description			
	U1	PIC12F529T39A	Microcontroller with integrated UHF transmitter			
	C6, C7	0.1 μF	Decoupling			
	R6	470 Ω	Current limiting			
Common	DS1	RED	LED			
Son	R3	10 kΩ	Weak pull-down for RF configuration			
	R4	100 Ω				
	R1, R5	47 kΩ	Voltage divider			
	C4	1000 pF				
	L5	120 nH				
	C5	100 pF				
붓	C3, L1, L3	Ω				
434 MHz	L4	39 nH	Matching to 50 Ω			
43,	C2	6.8 pF	1910011119 to 50 52			
	L2	2.2 nH				
	X1	24 MHz				
	L5	12 nH				
	C5	1 pF				
ł	C3, L4	DNP				
868 MHz	L3	27 nH	Matching to 50 Ω			
868	C2	2.7 pF	7			
	L1, L2	0Ω				
	X1	26 MHz				
	L5	8.2 nH				
915 MHz	L1, L4, C2	0Ω				
	C5	4.7 pF	1			
	C3	1.2 pF	Matching to 50 Ω			
916	L3	2.4 nH				
	L2	10 nH				
	X1	26 MHz				

10.0 INSTRUCTION SET SUMMARY

The PIC12F529T39A instruction set is highly orthogonal and is comprised of three basic categories.

- Byte-oriented operations
- · Bit-oriented operations
- · Literal and control operations

Each PIC12F529T39A instruction is a 12-bit word divided into an **opcode**, which specifies the instruction type, and one or more **operands** which further specify the operation of the instruction. The formats for each of the categories is presented in Figure 10-1, while the various opcode fields are summarized in Table 10-1.

For **byte-oriented** instructions, 'f' represents a file register designator and 'd' represents a destination designator. The file register designator specifies which file register is to be used by the instruction.

The destination designator specifies where the result of the operation is to be placed. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed in the file register specified in the instruction.

For **bit-oriented** instructions, 'b' represents a bit field designator which selects the number of the bit affected by the operation, while 'f' represents the number of the file in which the bit is located.

For **literal and control** operations, 'k' represents an 8 or 9-bit constant or literal value.

TABLE 10-1: OPCODE FIELD DESCRIPTIONS

Field	Description
f	Register file address (0x00 to 0x7F)
W	Working register (accumulator)
b	Bit address within an 8-bit file register
k	Literal field, constant data or label
х	Don't care location (= 0 or 1) The assembler will generate code with x = 0. It is the recommended form of use for compatibility with all Microchip software tools.
d	Destination select; d = 0 (store result in W) d = 1 (store result in file register 'f') Default is d = 1
label	Label name
TOS	Top-of-Stack
PC	Program Counter
WDT	Watchdog Timer counter
TO	Time-out bit
PD	Power-down bit
dest	Destination, either the W register or the specified register file location
[]	Options
()	Contents
\rightarrow	Assigned to
< >	Register bit field
€	In the set of
italics	User defined term (font is courier)

All instructions are executed within a single instruction cycle, unless a conditional test is true or the program counter is changed as a result of an instruction. In this case, the execution takes two instruction cycles. One instruction cycle consists of four oscillator periods. Thus, for an oscillator frequency of 4 MHz, the normal instruction execution time is 1 μ s. If a conditional test is true or the program counter is changed as a result of an instruction, the instruction execution time is 2 μ s.

Figure 10-1 shows the three general formats that the instructions can have. All examples in the figure use the following format to represent a hexadecimal number:

0xhhh

where 'h' signifies a hexadecimal digit.

FIGURE 10-1: GENERAL FORMAT FOR INSTRUCTIONS

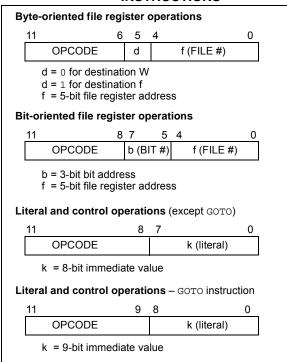


TABLE 10-2: INSTRUCTION SET SUMMARY

Mnemonic,		Description		12-Bit Opcode			Status	Notes
Opera	nds	Description C		MSb	b LSb		Affected	Notes
ADDWF	f, d	Add W and f	1	0001	11df	ffff	C, DC, Z	1, 2, 4
ANDWF	f, d	AND W with f	1	0001	01df	ffff	Z	2, 4
CLRF	f	Clear f	1	0000	011f	ffff	Z	4
CLRW	_	Clear W	1	0000	0100	0000	Z	
COMF	f, d	Complement f	1	0010	01df	ffff	Z	
DECF	f, d	Decrement f	1	0000	11df	ffff	Z	2, 4
DECFSZ	f, d	Decrement f, Skip if 0	1 ⁽²⁾	0010	11df	ffff	None	2, 4
INCF	f, d	Increment f	1	0010	10df	ffff	Z	2, 4
INCFSZ	f, d	Increment f, Skip if 0	1 ⁽²⁾	0011	11df	ffff	None	2, 4
IORWF	f, d	Inclusive OR W with f	1	0001	00df	ffff	Z	2, 4
MOVF	f, d	Move f	1	0010	00df	ffff	Z	2, 4
MOVWF	f	Move W to f	1	0000	001f	ffff	None	1, 4
NOP	_	No Operation	1	0000	0000	0000	None	
RLF	f, d	Rotate left f through Carry	1	0011	01df	ffff	С	2, 4
RRF	f, d	Rotate right f through Carry	1	0011	00df	ffff	С	2, 4
SUBWF	f, d	Subtract W from f	1	0000	10df	ffff	C, DC, Z	1, 2, 4
SWAPF	f, d	Swap f	1	0011	10df	ffff	None	2, 4
XORWF	f, d	Exclusive OR W with f	1	0001	10df	ffff	Z	2, 4
		BIT-ORIENTED FILE REGISTE	R OPERA	ATIONS	;			
BCF	f, b	Bit Clear f	1	0100	bbbf	ffff	None	2, 4
BSF	f, b	Bit Set f	1	0101	bbbf	ffff	None	2, 4
BTFSC	f, b	Bit Test f, Skip if Clear	1(2)	0110	bbbf	ffff	None	-
BTFSS	f, b	Bit Test f, Skip if Set	1 ⁽²⁾	0111	bbbf	ffff	None	
		LITERAL AND CONTROL O	PERATION	ONS				
ANDLW	k	AND literal with W	1	1110	kkkk	kkkk	Z	
CALL	k	Call Subroutine	2	1001	kkkk	kkkk	None	1
CLRWDT	_	Clear Watchdog Timer	1	0000	0000	0100	TO, PD	
GOTO	k	Unconditional branch	2	101k	kkkk	kkkk	None	
IORLW	k	Inclusive OR literal with W	1	1101	kkkk	kkkk	Z	
MOVLW	k	Move literal to W	1	1100	kkkk	kkkk	None	
MOVLB	k	Move literal to BSR	1	0000	0001	0kkk	None	
OPTION	_	Load OPTION register	1	0000	0000	0010	None	
RETLW	k	Return, place literal in W	2	1000	kkkk	kkkk	None	
SLEEP	_	Go into Standby mode	1	0000	0000	0011	$\overline{TO}, \overline{PD}$	3
TRIS	f	Load TRISGPIO register	1	0000	0000	Offf	None	
XORLW	k	Exclusive OR literal to W	1	1111	kkkk	kkkk	Z	

- **Note 1:** The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO. See Section 4.6 "Program Counter".
 - 2: When an I/O register is modified as a function of itself (e.g. MOVF GPIO, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.
 - **3:** The instruction TRIS f, where f = 6, causes the contents of the W register to be written to the tri-state latches of GPIO. A '1' forces the pin to a high-impedance state and disables the output buffers.
 - **4:** If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

ADDWF	Add W and f
Syntax:	[label] ADDWF f,d
Operands:	$0 \le f \le 31$ $d \in [0,1]$
Operation:	$(W) + (f) \to (dest)$
Status Affected:	C, DC, Z
Description:	Add the contents of the W register and register 'f'. If 'd' is'0', the result is stored in the W register. If 'd' is '1', the result is stored back in

BCF	Bit Clear f
Syntax:	[label] BCF f,b
Operands:	$\begin{aligned} 0 &\leq f \leq 31 \\ 0 &\leq b \leq 7 \end{aligned}$
Operation:	$0 \rightarrow (f < b >)$
Status Affected:	None
Description:	Bit 'b' in register 'f' is cleared.

ANDLW	AND literal with W
Syntax:	[label] ANDLW k
Operands:	$0 \leq k \leq 255$
Operation:	(W).AND. $(k) \rightarrow (W)$
Status Affected:	Z
Description:	The contents of the W register are AND'ed with the 8-bit literal 'k'. The result is placed in the W register.

register 'f'.

BSF	Bit Set f
Syntax:	[label] BSF f,b
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$
Operation:	$1 \rightarrow (f < b >)$
Status Affected:	None
Description:	Bit 'b' in register 'f' is set.

ANDWF	AND W with f
Syntax:	[label] ANDWF f,d
Operands:	$0 \le f \le 31$ $d \in [0,1]$
Operation:	(W) .AND. (f) \rightarrow (dest)
Status Affected:	Z
Description:	The contents of the W register are AND'ed with register 'f'. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.

BTFSC	Bit Test f, Skip if Clear
Syntax:	[label] BTFSC f,b
Operands:	$\begin{aligned} 0 &\leq f \leq 31 \\ 0 &\leq b \leq 7 \end{aligned}$
Operation:	skip if $(f < b >) = 0$
Status Affected:	None
Description:	If bit 'b' in register 'f' is '0', then the next instruction is skipped.
	If bit 'b' is '0', then the next instruction fetched during the current instruction execution is discarded, and a NOP is executed instead, making this a 2-cycle instruction.

BTFSS	Bit Test f, Skip if Set
Syntax:	[label] BTFSS f,b
Operands:	$0 \le f \le 31$ $0 \le b < 7$
Operation:	skip if (f) = 1
Status Affected:	None
Description:	If bit 'b' in register 'f' is '1', then the next instruction is skipped.
	If bit 'b' is '1', then the next instruc- tion fetched during the current instruction execution, is discarded

and a NOP is executed instead, making this a 2-cycle instruction.

CLRW	Clear W
Syntax:	[label] CLRW
Operands:	None
Operation:	$00h \rightarrow (W);$ $1 \rightarrow Z$
Status Affected:	Z
Description:	The W register is cleared. Zero bit (Z) is set.

CALL	Subroutine Call
Syntax:	[label] CALL k
Operands:	$0 \leq k \leq 255$
Operation:	(PC) + 1 \rightarrow Top-of-Stack; k \rightarrow PC<7:0>; (STATUS<6:5>) \rightarrow PC<10:9>; 0 \rightarrow PC<8>
Status Affected:	None
Description:	Subroutine call. First, return address (PC + 1) is pushed onto the stack. The 8-bit immediate address is loaded into PC bits <7:0>. The upper bits PC<10:9> are loaded from STATUS<6:5>, PC<8> is cleared. CALL is a 2-cycle instruction.

CLRWDT	Clear Watchdog Timer
Syntax:	[label] CLRWDT
Operands:	None
Operation:	00h → WDT; 0 → WDT prescaler (if assigned); 1 → \overline{TO} ; 1 → \overline{PD}
Status Affected:	TO, PD
Description:	The CLRWDT instruction resets the WDT. It also resets the prescaler, if the prescaler is assigned to the WDT and not Timer0. Status bits TO and PD are set.

Syntax:	[label] CLRF f
Operands:	$0 \leq f \leq 31$
Operation:	$00h \rightarrow (f);$ $1 \rightarrow Z$
Status Affected:	Z
Description:	The contents of register 'f' are cleared and the Z bit is set.

Clear f

CLRF

COMF	Complement f	
Syntax:	[label] COMF f,d	
Operands:	$\begin{aligned} 0 &\leq f \leq 31 \\ d &\in [0,1] \end{aligned}$	
Operation:	$(\bar{f}) \to (dest)$	
Status Affected:	Z	
Description:	The contents of register 'f' are complemented. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.	

DECF	Decrement f
Syntax:	[label] DECF f,d
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$
Operation:	$(f)-1 \rightarrow (dest)$
Status Affected:	Z
Description:	Decrement register 'f'. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.

DECFSZ	Decrement f, Skip if 0		
Syntax:	[label] DECFSZ f,d		
Operands:	$0 \le f \le 31$ $d \in [0,1]$		
Operation:	$(f) - 1 \rightarrow d$; skip if result = 0		
Status Affected:	None		
Description:	The contents of register 'f' are decremented. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed back in register 'f'.		
	If the result is '0', the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a 2-cycle instruction.		

GOTO	Unconditional Branch		
Syntax:	[label] GOTO k		
Operands:	$0 \leq k \leq 511$		
Operation:	$k \rightarrow PC<8:0>$; STATUS<6:5> $\rightarrow PC<10:9>$		
Status Affected:	None		
Description:	GOTO is an unconditional branch. The 9-bit immediate value is loaded into PC bits <8:0>. The upper bits of PC are loaded from STATUS<6:5>. GOTO is a 2-cycle instruction.		

INCF	Increment f
Syntax:	[label] INCF f,d
Operands:	$0 \le f \le 31$ $d \in [0,1]$
Operation:	$(f) + 1 \rightarrow (dest)$
Status Affected:	Z
Description:	The contents of register 'f' are incremented. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed back in register 'f'.

INCFSZ	Increment f, Skip if 0	
Syntax:	[label] INCFSZ f,d	
Operands:	$\begin{aligned} 0 &\leq f \leq 31 \\ d &\in [0,1] \end{aligned}$	
Operation:	(f) + 1 \rightarrow (dest), skip if result = 0	
Status Affected:	None	
Description:	The contents of register 'f' are incremented. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed back in register 'f'.	
	If the result is '0', then the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a 2-cycle instruction.	

IORLW	Inclusive OR literal with W		
Syntax:	[label] IORLW k		
Operands:	$0 \leq k \leq 255$		
Operation:	(W) .OR. $(k) \rightarrow (W)$		
Status Affected:	Z		
Description:	The contents of the W register are OR'ed with the 8-bit literal 'k'. The result is placed in the W register.		

IORWFInclusive OR W with fSyntax:[label]IORWFf,dOperands: $0 \le f \le 31$
 $d \in [0,1]$ Operation:(W).OR. (f) \rightarrow (dest)Status Affected:ZDescription:Inclusive OR the W register with register 'f'. If 'd' is '0', the result is placed in the W register. If 'd' is '1',

'f'.

the result is placed back in register

test of a file register, since status

MOVWFMove W to fSyntax:[label] MOVWF fOperands: $0 \le f \le 31$ Operation: $(W) \rightarrow (f)$ Status Affected:NoneDescription:Move data from the W register to register 'f'.

MOVF Move f Syntax: [label] MOVF f,d Operands: $0 \le f \le 31$ $d \in [0,1]$ Operation: $(f) \rightarrow (dest)$ Status Affected: Ζ Description: The contents of register 'f' are moved to destination 'd'. If 'd' is '0', destination is the W register. If 'd' is '1', the destination is file register 'f'. 'd' = 1 is useful as a

NOP No Operation

Syntax: [label] NOP

Operands: None

Operation: No operation

Status Affected: None

Description: No operation.

MOVLBMove literal to BSRSyntax:[label] MOVLBkOperands: $0 \le k \le 7$ Operation: $k \to BSR$ Status Affected:NoneDescription:The 3-bit literal 'k' is loaded into the Bank Select Register (BSR). The "don't cares" will be assembled at '0'.

flag Z is affected.

 OPTION
 Load OPTION Register

 Syntax:
 [label] Option

 Operands:
 None

 Operation:
 (W) → Option

 Status Affected:
 None

 Description:
 The content of the W register is loaded into the OPTION register.

MOVLWMove Literal to WSyntax:[label]MOVLW kOperands: $0 \le k \le 255$ Operation: $k \to (W)$ Status Affected:NoneDescription:The 8-bit literal 'k' is loaded into the W register. The "don't cares" will assembled as '0's.

RETLW	Return with Literal in W		
Syntax:	[label] RETLW k		
Operands:	$0 \leq k \leq 255$		
Operation:	$k \rightarrow (W);$ TOS \rightarrow PC		
Status Affected:	None		
Description:	The W register is loaded with the 8-bit literal 'k'. The program counter is loaded from the top of the stack (the return address). This is a 2-cycle instruction.		

SLEEP	Enter SLEEP Mode
Syntax:	[label] SLEEP
Operands:	None
Operation:	$\begin{array}{l} \text{00h} \rightarrow \text{WDT;} \\ \text{0} \rightarrow \underline{\text{WDT}} \text{ prescaler;} \\ \text{1} \rightarrow \underline{\overline{\text{TO}}}; \\ \text{0} \rightarrow \overline{\text{PD}} \end{array}$
Status Affected:	TO, PD, GPWUF
Description:	Time-out Status bit (TO) is set. The Power-down Status bit (PD) is cleared. GPWUF is unaffected. The WDT and its prescaler are cleared. The processor is put into Sleep
	mode with the oscillator stopped. See Section 8.8 "Power-down Mode (Sleep)" on Sleep for more details.

RLF	Rotate Left f through Carry			
Syntax:	[label]	RLF f,d		
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	See description below			
Status Affected:	С			
Description:	The contents of register 'f' are rotated one bit to the left through the Carry flag. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is stored back in register 'f'.			

SUBWF	Subtract W from f		
Syntax:	[label] SUBWF f,d		
Operands:	$0 \le f \le 31$ $d \in [0,1]$		
Operation:	$(f) - (W) \rightarrow (dest)$		
Status Affected:	C, DC, Z		
Description:	Subtract (two's complement method) the W register from register 'f'. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.		

RRF	Rotate Right f through Carry			
Syntax:	[label] RRF f,d			
Operands:	$\begin{aligned} 0 &\leq f \leq 31 \\ d &\in [0,1] \end{aligned}$			
Operation:	See description below			
Status Affected:	С			
Description:	The contents of register 'f' are rotated one bit to the right through the Carry flag. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed back in register 'f'.			
	C register 'f'			

SWAPF	Swap Nibbles in f
Syntax:	[label] SWAPF f,d
Operands:	$0 \le f \le 31$ $d \in [0,1]$
Operation:	$(f<3:0>) \rightarrow (dest<7:4>);$ $(f<7:4>) \rightarrow (dest<3:0>)$
Status Affected:	None
Description:	The upper and lower nibbles of register 'f' are exchanged. If 'd' is '0', the result is placed in W register. If 'd' is '1', the result is placed in register 'f'.

TRIS	Load TRIS Register				
Syntax:	[label] TRIS f				
Operands:	f = 6				
Operation:	$\text{(W)} \rightarrow \text{TRIS register f}$				
Status Affected:	None				
Description:	TRIS register 'f' (f = 6 or 7) is loaded with the contents of the W register.				
XORLW	Exclusive OR literal with W				
XORLW Syntax:	Exclusive OR literal with W [label] XORLW k				
Syntax:	[label] XORLW k				
Syntax: Operands:	[<i>label</i>] XORLW k 0 ≤ k ≤ 255				

XORWF	Exclusive OR W with f			
Syntax:	[label] XORWF f,d			
Operands:	$0 \le f \le 31$ $d \in [0,1]$			
Operation:	(W) .XOR. (f) \rightarrow (dest)			
Status Affected:	Z			
Description:	Exclusive OR the contents of the W register with register 'f'. If 'd' is '0', the result is stored in the W register. If 'd' is '1', the result is stored back in register 'f'.			

11.0 DEVELOPMENT SUPPORT

The PIC[®] microcontrollers (MCU) and dsPIC[®] digital signal controllers (DSC) are supported with a full range of software and hardware development tools:

- · Integrated Development Environment
 - MPLAB® X IDE Software
- · Compilers/Assemblers/Linkers
 - MPLAB XC Compiler
 - MPASMTM Assembler
 - MPLINK[™] Object Linker/ MPLIB[™] Object Librarian
 - MPLAB Assembler/Linker/Librarian for Various Device Families
- Simulators
 - MPLAB X SIM Software Simulator
- Emulators
 - MPLAB REAL ICE™ In-Circuit Emulator
- · In-Circuit Debuggers/Programmers
 - MPLAB ICD 3
 - PICkit™ 3
- · Device Programmers
 - MPLAB PM3 Device Programmer
- Low-Cost Demonstration/Development Boards, Evaluation Kits and Starter Kits
- · Third-party development tools

11.1 MPLAB X Integrated Development Environment Software

The MPLAB X IDE is a single, unified graphical user interface for Microchip and third-party software, and hardware development tool that runs on Windows[®], Linux and Mac OS[®] X. Based on the NetBeans IDE, MPLAB X IDE is an entirely new IDE with a host of free software components and plug-ins for high-performance application development and debugging. Moving between tools and upgrading from software simulators to hardware debugging and programming tools is simple with the seamless user interface.

With complete project management, visual call graphs, a configurable watch window and a feature-rich editor that includes code completion and context menus, MPLAB X IDE is flexible and friendly enough for new users. With the ability to support multiple tools on multiple projects with simultaneous debugging, MPLAB X IDE is also suitable for the needs of experienced users.

Feature-Rich Editor:

- · Color syntax highlighting
- Smart code completion makes suggestions and provides hints as you type
- Automatic code formatting based on user-defined rules
- · Live parsing

User-Friendly, Customizable Interface:

- Fully customizable interface: toolbars, toolbar buttons, windows, window placement, etc.
- · Call graph window

Project-Based Workspaces:

- · Multiple projects
- · Multiple tools
- · Multiple configurations
- · Simultaneous debugging sessions

File History and Bug Tracking:

- · Local file history feature
- · Built-in support for Bugzilla issue tracker

11.2 MPLAB XC Compilers

The MPLAB XC Compilers are complete ANSI C compilers for all of Microchip's 8, 16, and 32-bit MCU and DSC devices. These compilers provide powerful integration capabilities, superior code optimization and ease of use. MPLAB XC Compilers run on Windows, Linux or MAC OS X.

For easy source level debugging, the compilers provide debug information that is optimized to the MPLAB X IDE.

The free MPLAB XC Compiler editions support all devices and commands, with no time or memory restrictions, and offer sufficient code optimization for most applications.

MPLAB XC Compilers include an assembler, linker and utilities. The assembler generates relocatable object files that can then be archived or linked with other relocatable object files and archives to create an executable file. MPLAB XC Compiler uses the assembler to produce its object file. Notable features of the assembler include:

- · Support for the entire device instruction set
- Support for fixed-point and floating-point data
- · Command-line interface
- · Rich directive set
- · Flexible macro language
- MPLAB X IDE compatibility

11.3 MPASM Assembler

The MPASM Assembler is a full-featured, universal macro assembler for PIC10/12/16/18 MCUs.

The MPASM Assembler generates relocatable object files for the MPLINK Object Linker, Intel® standard HEX files, MAP files to detail memory usage and symbol reference, absolute LST files that contain source lines and generated machine code, and COFF files for debugging.

The MPASM Assembler features include:

- Integration into MPLAB X IDE projects
- User-defined macros to streamline assembly code
- Conditional assembly for multipurpose source files
- Directives that allow complete control over the assembly process

11.4 MPLINK Object Linker/ MPLIB Object Librarian

The MPLINK Object Linker combines relocatable objects created by the MPASM Assembler. It can link relocatable objects from precompiled libraries, using directives from a linker script.

The MPLIB Object Librarian manages the creation and modification of library files of precompiled code. When a routine from a library is called from a source file, only the modules that contain that routine will be linked in with the application. This allows large libraries to be used efficiently in many different applications.

The object linker/library features include:

- Efficient linking of single libraries instead of many smaller files
- Enhanced code maintainability by grouping related modules together
- Flexible creation of libraries with easy module listing, replacement, deletion and extraction

11.5 MPLAB Assembler, Linker and Librarian for Various Device Families

MPLAB Assembler produces relocatable machine code from symbolic assembly language for PIC24, PIC32 and dsPIC DSC devices. MPLAB XC Compiler uses the assembler to produce its object file. The assembler generates relocatable object files that can then be archived or linked with other relocatable object files and archives to create an executable file. Notable features of the assembler include:

- · Support for the entire device instruction set
- Support for fixed-point and floating-point data
- · Command-line interface
- · Rich directive set
- · Flexible macro language
- · MPLAB X IDE compatibility

11.6 MPLAB X SIM Software Simulator

The MPLAB X SIM Software Simulator allows code development in a PC-hosted environment by simulating the PIC MCUs and dsPIC DSCs on an instruction level. On any given instruction, the data areas can be examined or modified and stimuli can be applied from a comprehensive stimulus controller. Registers can be logged to files for further run-time analysis. The trace buffer and logic analyzer display extend the power of the simulator to record and track program execution, actions on I/O, most peripherals and internal registers.

The MPLAB X SIM Software Simulator fully supports symbolic debugging using the MPLAB XC Compilers, and the MPASM and MPLAB Assemblers. The software simulator offers the flexibility to develop and debug code outside of the hardware laboratory environment, making it an excellent, economical software development tool.

11.7 MPLAB REAL ICE In-Circuit Emulator System

The MPLAB REAL ICE In-Circuit Emulator System is Microchip's next generation high-speed emulator for Microchip Flash DSC and MCU devices. It debugs and programs all 8, 16 and 32-bit MCU, and DSC devices with the easy-to-use, powerful graphical user interface of the MPLAB X IDE.

The emulator is connected to the design engineer's PC using a high-speed USB 2.0 interface and is connected to the target with either a connector compatible with in-circuit debugger systems (RJ-11) or with the new high-speed, noise tolerant, Low-Voltage Differential Signal (LVDS) interconnection (CAT5).

The emulator is field upgradable through future firmware downloads in MPLAB X IDE. MPLAB REAL ICE offers significant advantages over competitive emulators including full-speed emulation, run-time variable watches, trace analysis, complex breakpoints, logic probes, a ruggedized probe interface and long (up to three meters) interconnection cables.

11.8 MPLAB ICD 3 In-Circuit Debugger System

The MPLAB ICD 3 In-Circuit Debugger System is Microchip's most cost-effective, high-speed hardware debugger/programmer for Microchip Flash DSC and MCU devices. It debugs and programs PIC Flash microcontrollers and dsPIC DSCs with the powerful, yet easy-to-use graphical user interface of the MPLAB IDE.

The MPLAB ICD 3 In-Circuit Debugger probe is connected to the design engineer's PC using a high-speed USB 2.0 interface and is connected to the target with a connector compatible with the MPLAB ICD 2 or MPLAB REAL ICE systems (RJ-11). MPLAB ICD 3 supports all MPLAB ICD 2 headers.

11.9 PICkit 3 In-Circuit Debugger/ Programmer

The MPLAB PICkit 3 allows debugging and programming of PIC and dsPIC Flash microcontrollers at a most affordable price point using the powerful graphical user interface of the MPLAB IDE. The MPLAB PICkit 3 is connected to the design engineer's PC using a full-speed USB interface and can be connected to the target via a Microchip debug (RJ-11) connector (compatible with MPLAB ICD 3 and MPLAB REAL ICE). The connector uses two device I/O pins and the Reset line to implement in-circuit debugging and In-Circuit Serial Programming™ (ICSP™).

11.10 MPLAB PM3 Device Programmer

The MPLAB PM3 Device Programmer is a universal, CE compliant device programmer with programmable voltage verification at VDDMIN and VDDMAX for maximum reliability. It features a large LCD display (128 x 64) for menus and error messages, and a modular, detachable socket assembly to support various package types. The ICSP cable assembly is included as a standard item. In Stand-Alone mode, the MPLAB PM3 Device Programmer can read, verify and program PIC devices without a PC connection. It can also set code protection in this mode. The MPLAB PM3 connects to the host PC via an RS-232 or USB cable. The MPLAB PM3 has high-speed communications and optimized algorithms for quick programming of large memory devices, and incorporates an MMC card for file storage and data applications.

11.11 Demonstration/Development Boards, Evaluation Kits, and Starter Kits

A wide variety of demonstration, development and evaluation boards for various PIC MCUs and dsPIC DSCs allows quick application development on fully functional systems. Most boards include prototyping areas for adding custom circuitry and provide application firmware and source code for examination and modification.

The boards support a variety of features, including LEDs, temperature sensors, switches, speakers, RS-232 interfaces, LCD displays, potentiometers and additional EEPROM memory.

The demonstration and development boards can be used in teaching environments, for prototyping custom circuits and for learning about various microcontroller applications.

In addition to the PICDEM™ and dsPICDEM™ demonstration/development board series of circuits, Microchip has a line of evaluation kits and demonstration software for analog filter design, Keelog® security ICs, CAN, IrDA®, PowerSmart battery management, SEEVAL® evaluation system, Sigma-Delta ADC, flow rate sensing, plus many more.

Also available are starter kits that contain everything needed to experience the specified device. This usually includes a single application and debug capability, all on one board.

Check the Microchip web page (www.microchip.com) for the complete list of demonstration, development and evaluation kits.

11.12 Third-Party Development Tools

Microchip also offers a great collection of tools from third-party vendors. These tools are carefully selected to offer good value and unique functionality.

- Device Programmers and Gang Programmers from companies, such as SoftLog and CCS
- Software Tools from companies, such as Gimpel and Trace Systems
- Protocol Analyzers from companies, such as Saleae and Total Phase
- Demonstration Boards from companies, such as MikroElektronika, Digilent[®] and Olimex
- Embedded Ethernet Solutions from companies, such as EZ Web Lynx, WIZnet and IPLogika[®]

12.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings(†)

Ambient temperature under bias40°C to +	+85°C
Storage temperature55°C to +1	150°C
Voltage on VDD with respect to Vss	+6.5V
Voltage on VDDRF with respect to VSSRF	+3.9V
Voltage on MCLR with respect to Vss	13.5V
Voltage on all other pins with respect to Vss0.3V to (VDD +	0.3V)
Total power dissipation ⁽¹⁾	0 mW
Max. current out of Vss pin)0 mA
Max. current into VDD pin	50 mA
Input clamp current, IiK (VI < 0 or VI > VDD)±2	20 mA
Output clamp current, IOK (Vo < 0 or Vo > VDD)	20 mA
Max. output current sunk by any I/O pin2	25 mA
Max. output current sourced by any I/O pin2	25 mA
Max. output current sourced by I/O port	75 mA
Max. output current sunk by I/O port	75 mA
Note 1: Power dissipation is calculated as follows: PDIS = VDD x {IDD $-\Sigma$ IOH} + Σ {(VDD $-$ VOH) x IOH} + Σ (VO	

[†]NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

12.1 RF Transmitter Electrical Specifications

Symbol	Description	Conditions	Min.	Тур.	Max.	Unit
Current Consumption						
IDDSL	Supply Current in Sleep mode	_	_	0.5	1	μΑ
IDDT_315	Supply Current in Transmit mode at 315 MHz*	RFOP = +10 dBm 50% OOK RFOP = +10 dBm FSK RFOP = 0 dBm FSK	_	11 15 9	_ _	mA mA mA
IDDT_915	Supply Current in Transmit mode at 915 MHz*	RFOP = +10 dBm FSK RFOP = 0 dBm FSK	_	17.5 10.5		mA mA
RF and Baseband Specifications						
FBAND	Accessible Frequency Bands	Band 0, with FXOSC = 22 MHz	310	_	450	MHz
	See details in Table 7	Band 0, with FXOSC = 24 MHz	312	_	450	MHz
		Band 0, with FXOSC = 26 MHz	338	_	450	MHz
		Band 1, with FXOSC = 26 MHz	860 902	_	870 928	MHz MHz
FDA	Frequency deviation, FSK	_	10	_	200	kHz
BRF	Bit rate, FSK	Permissible Range	0.5	_	100	kbps
BRO	Bit rate, OOK	Permissible Range	0.5	_	10	kbps
OOK_B	OOK Modulation Depth	_	_	45	_	dB
RFOP	RF output power in 50 Ohms in either frequency bands	High-Power Setting Low-Power Setting*	7 -3	10 0	_	dBm dBm
RFOPFL	RF output power flatness	From 315 to 390 MHz	_	2	_	dB
DRFOPV	Variation in RF output power with supply voltage	2.5V to 3.3V 1.8V to 3.7V	_	_	3 7	dB dB
PHN	Transmitter phase noise	At offset: 100 kHz 350 kHz 550 kHz 1.15 MHz		-82 -92 -96 -103	-76 -81 -91 -101	dBc/Hz dBc/Hz dBc/Hz dBc/Hz
STEP_22	RF frequency step	FXOSC = 22 MHz, Band 0	_	1.34277	_	kHz
STEP_24	RF frequency step	FXOSC = 24 MHz, Band 0	_	1.46484	_	kHz
STEP_26	RF frequency step	FXOSC = 26 MHz, Band 0 FXOSC = 26 MHz, Band 1	_	1.58691 3.17383	_	kHz kHz
FXOSC	Crystal Oscillator Frequency	_	_	22 24	_	MHz MHz
				26	_	MHz
Timing Spec		,		•	T	
t _{WAKE}	Time from Sleep to Tx mode	XTAL dependant, with spec'd XTAL	_	650	2000	us
t _{OFFT}	Timer from Tx data activity to Sleep	Programmable	_	2 20	_ _	ms ms
t _{RAMP}	PA Ramp up and down time	_	_	20	_	us
t _{START}	Time before CTRL pin mode selection	Time from power on to sampling of CTRL	_	1	_	ms
f _{CTRL}	CTRL Clock Frequency	_	_		10	MHz
t _{CH}	CTRL Clock High time	_	45	_	_	ns
t _{CL}	CTRL Clock Low time	_	45	_	_	ns
t _{RISE}	CTRL Clock Rise time	_		_	5	ns
t _{FALL}	CTRL Clock Fall time	_		<u> </u>	5	ns

12.1 RF Transmitter Electrical Specifications

Symbol	Description	Conditions	Min.	Тур.	Max.	Unit
t _{SETUP}	DATA Setup time	From DATA transition to CTRL rising edge	45	_	_	ns
t _{HOLD}	DATA Hold time	From CTRL rising edge to DATA transition	45	_	_	ns
t ₀	Time at '1' on DATA during Recovery Sequence Timing	See Figure 9-4	_	_	5	ns
t ₁	Time at '0' on DATA during Recovery Sequence Timing	See Figure 9-4	5	_	_	ns

TABLE 12-1: POWER CONSUMPTION IN TX MODE

Frequency Band	Conditions	Typical Current Drain	
310 to 450 MHz	POUT = +10 dBm, OOK modulation with 50% duty cycle	11 mA	
	POUT = +10 dBm, FSK modulation	15 mA	
	POUT = 0 dBm, FSK modulation	9 mA	
860 to 870 MHz	POUT = +10 dBm, FSK modulation	16.5 mA	
	POUT = 0 dBm, FSK modulation	10 mA	
902 to 928 MHz	002 to 928 MHz POUT = +10 dBm, FSK modulation		
	POUT = 0 dBm, FSK modulation	10.5 mA	

FIGURE 12-1: PIC12F529T39A VOLTAGE-FREQUENCY GRAPH, -40°C ≤ TA ≤ +85°C

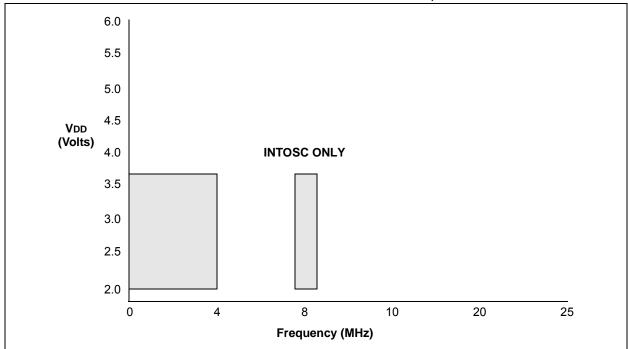
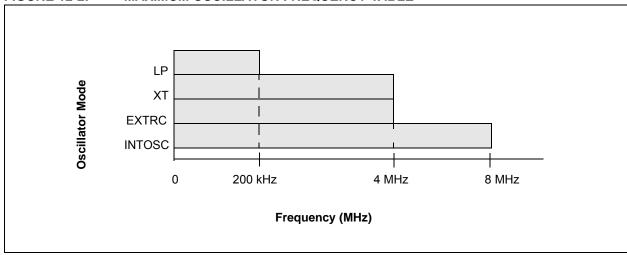


FIGURE 12-2: MAXIMUM OSCILLATOR FREQUENCY TABLE



12.2 DC Characteristics

TABLE 12-2: DC CHARACTERISTICS: PIC12F529T39A (INDUSTRIAL)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature -40°C \leq TA \leq +85°C (industrial)						
Param No.	Sym.	Characteristic	Min. Typ ⁽¹⁾ Ma		Max.	Units	Conditions		
D001	Vdd	Supply Voltage	2.0		3.7	V	See Figure 12-1		
D002	VDR	RAM Data Retention Voltage ⁽²⁾		1.5*	_	V	Device in Sleep mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 8.4 "Power-on Reset (POR)" for details		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 8.4 "Power-on Reset (POR)" for details		
D005	IDDP	Supply Current During Prog/ Erase.	_	250*	_	μА			
D010	IDD	Supply Current ^(3,4)	_	175	250	μΑ	Fosc = 4 MHz, VDD = 2.0V		
				250	400	μΑ	Fosc = 8 MHz, VDD = 2.0V		
			_	11	20	μΑ	Fosc = 32 kHz, VDD = 2.0V		
D020	IPD	Power-down Current ⁽⁵⁾	_	0.1	1.2	μΑ	V _{DD} = 2.0V		
D022	IWDT	WDT Current		1.0	3.0	μΑ	V _{DD} = 2.0V		

^{*} These parameters are characterized but not tested.

- **Note 1:** Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
 - 2: This is the limit to which VDD can be lowered in Sleep mode without losing RAM data.
 - **3:** The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - 4: The test conditions for all IDD measurements in active operation mode are:

 OSC1 = external square wave, from rail-to-rail for external clock modes; all I/O pins tri-stated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - **5:** For standby current measurements, the conditions are the same as IDD, except that the device is in Sleep mode. If a module current is listed, the current is for that specific module enabled and the device in Sleep.

TABLE 12-3: DC CHARACTERISTICS: PIC12F529T39A (Industrial)

DC CHA	ARACTE	RISTICS	Operating to	- emperat	Standard Operating Conditions (unless otherwise specified) Operating temperature $-40^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$ (industrial) Operating voltage VDD range as described in DC specification.						
Param No.	Sym.	Characteristic	Min.	Тур†	Max.	Units	Conditions				
	VIL	Input Low Voltage									
		I/O ports									
D030A			Vss	_	0.15 VDD	V	Otherwise				
D031		with Schmitt Trigger buffer	Vss	_	0.15 VDD	V					
D032		MCLR, TOCKI	Vss	_	0.15 VDD	V					
D033		OSC1 (EXTRC mode)	Vss	_	0.15 VDD	V	(Note 1)				
D033A		OSC1 (XT and LP modes)	Vss	_	0.3	V					
	VIH	Input High Voltage				•					
		I/O ports		_							
D040A			0.25 VDD + 0.8V	_	VDD	V	Otherwise				
D041		with Schmitt Trigger buffer	0.85 VDD	_	VDD	V	For entire VDD range				
D042		MCLR, T0CKI	0.85 VDD	_	VDD	V					
D042A		OSC1 (EXTRC mode)	0.85 VDD	_	VDD	V	(Note 1)				
D043		OSC1 (XT and LP modes)	1.6	_	VDD	V					
D070	IPUR	I/O PORT weak pull-up current ⁽⁵⁾	50	250	400	μΑ	VDD = 3.7V, VPIN = VSS				
,	IIL	Input Leakage Current ^{(2), (3)}									
D060		I/O ports	_	_	±1	μА	Vss ≤ VPIN ≤ VDD, Pin at high-impedance				
D061		GP3/MCLR ⁽⁴⁾	_	±0.7	±5	μΑ	$Vss \leq V \text{PIN} \leq V \text{DD}$				
D063		OSC1	_	_	±5	μА	$\label{eq:VSS} VSS \leq VPIN \leq VDD, \ XT \ and \ LP \\ osc \ configuration$				
		Output Low Voltage									
D080		I/O ports	_	_	0.6	V	IOL = 8.5 mA, VDD = 4.5V, – 40°C to +85°C				
		Output High Voltage									
D090		I/O ports ⁽³⁾	VDD - 0.7	_	_	V	IOH = -3.0 mA, VDD = 4.5V, - 40°C to +85°C				
		Capacitive Loading Specs on Output F	ins								
D101		All I/O pins	_	_	50	pF					
		Flash Data Memory	•	•			•				
D120	ED	Byte endurance	100K	1M	_	E/W	$-40^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$				
D121	VDRW	VDD for read/write	VMIN	_	3.7	V					

[†] Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

- Note 1: In EXTRC oscillator configuration, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC12F529T39A be driven with external clock in RC mode.
 - 2: The leakage current on the MCLR pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.
 - **3:** Negative current is defined as coming out of the pin.
 - 4: This specification applies to GP3/MCLR configured as GP3 with internal pull-up disabled.
 - 5: This specification applies to all weak pull-up devices, including the weak pull-up found on GP3/MCLR. The current value listed will be the same whether or not the pin is configured as GP3 with pull-up enabled or MCLR.

TABLE 12-4: PULL-UP RESISTOR RANGES

VDD (Volts)	Temperature (°C)	Min.	Тур.	Max.	Units	
GP0/GP1						
2.0	-40	73K	105K	186K	Ω	
	25	73K	113K	187K	Ω	
	85	82K	123K	190K	Ω	
GP3						
2.0	-40	63K	81K	96K	Ω	
	25	77K	93K	116K	Ω	
	85	82K	96K	116K	Ω	

12.3 Timing Parameter Symbology and Load Conditions – PIC12F529T39A

The timing parameter symbols have been created following one of the following formats:

1. TppS2ppS

2. TppS

Т	
F Frequency	T Time

Lowercase subscripts (pp) and their meanings:

рр			
2	to	mc	MCLR
ck	CLKOUT	osc	Oscillator
су	Cycle time	os	OSC1
drt	Device Reset Timer	tO	T0CKI
io	I/O port	wdt	Watchdog Timer

Uppercase letters and their meanings:

S			
F	Fall	Р	Period
Н	High	R	Rise
1	Invalid (high-impedance)	V	Valid
L	Low	Z	High-impedance

FIGURE 12-3: LOAD CONDITIONS - PIC12F529T39A

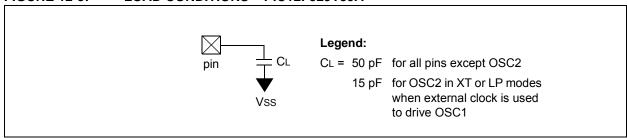
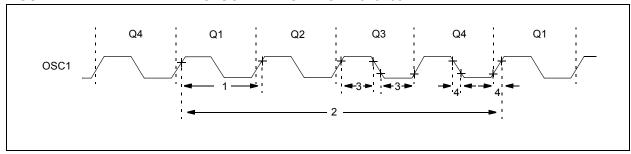


FIGURE 12-4: EXTERNAL CLOCK TIMING – PIC12F529T39A



12.4 AC Characteristics

TABLE 12-5: EXTERNAL CLOCK TIMING REQUIREMENTS

AC CHARACTERISTICS				Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$ (industrial), Operating Voltage VDD range is described in Section 12.0 "Electrical Characteristics".						
Param No.	Sym.	Characteristic	Min. Typ Max. Units Conditions							
1A	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	4	MHz	XT Oscillator mode			
			DC	_	200	kHz	LP Oscillator mode			
		Oscillator Frequency ⁽¹⁾	DC	_	4	MHz	EXTRC Oscillator mode			
			0.1	_	4	MHz	XT Oscillator mode			
			DC	_	200	kHz	LP Oscillator mode			
1	Tosc	External CLKIN Period ⁽¹⁾	250	_	_	ns	XT Oscillator mode			
			5	_	_	μS	LP Oscillator mode			
		Oscillator Period ⁽¹⁾	250	_	_	ns	EXTRC Oscillator mode			
			250	_	10,000	ns	XT Oscillator mode			
			5	_	_	μS	LP Oscillator mode			
2	TCY	Instruction Cycle Time	200	4/Fosc	DC	ns				
3	TosL,	Clock in (OSC1) Low or High	50*	_	_	ns	XT Oscillator			
	TosH	Time	2*	_	_	μS	LP Oscillator			
4	TosR,	Clock in (OSC1) Rise or Fall	_	_	25*	ns	XT Oscillator			
	TosF	Time	_	_	50*	ns	LP Oscillator			

^{*} These parameters are characterized but not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

TABLE 12-6: CALIBRATED INTERNAL RC FREQUENCIES

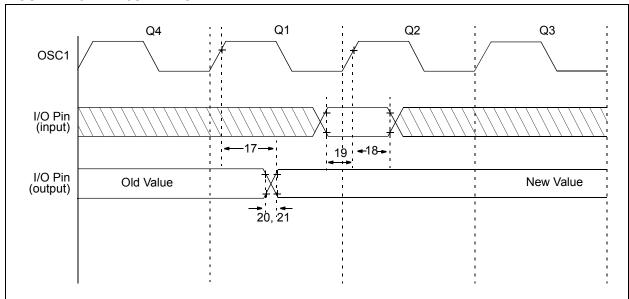
AC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$ (industrial), Operating Voltage VDD range is described in Section 12.0 "Electrical Characteristics".						
Param No.	Sym.	Characteristic	Freq. Tolerance Min. Typ† Max. Units Conditions						
F10	Fosc	Internal Calibrated INTOSC Frequency ⁽¹⁾	±1% ±2%	7.92 7.84	8.00 8.00	8.08 8.16		3.5V, 25°C 2.5V ≤ VDD ≤ 3.7V 0°C ≤ TA ≤ +85°C	
			±5%	7.60	8.00	8.40	MHz	$2.0V \le VDD \le 3.7V$ - $40^{\circ}C \le TA \le +85^{\circ}C \text{ (Ind.)}$	

These parameters are characterized but not tested.

Note 1: To ensure these oscillator frequency tolerances, VDD and VSS must be capacitively decoupled as close to the device as possible. 0.1 uF and 0.01 uF values in parallel are recommended.

[†] Data in the Typical ("Typ") column is at 3.7V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 12-5: I/O TIMING



Note: All tests must be done with specified capacitive loads (see data sheet) 50 pF on I/O pins and CLKOUT.

TABLE 12-7: TIMING REQUIREMENTS

AC CHARACTERISTICS		Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq \text{TA} \leq +85^{\circ}\text{C}$ (industrial) Operating Voltage VDD range is described in Section 12.0 "Electrical Characteristics".									
Param No. Sym.		Characteristic	Min.	Typ ⁽¹⁾	Max.	Units					
17	TosH2IOV	OSC1↑ (Q1 cycle) to Port Out Valid ^{(2), (3)}	_	_	100*	ns					
18	TosH2ioI	OSC1 [↑] (Q2 cycle) to Port Input Invalid (I/O in hold time) ⁽²⁾	50	_	_	ns					
19	TioV2osH	Port Input Valid to OSC1 [↑] (I/O in setup time)	20	_	_	ns					
20	TioR	Port Output Rise Time ⁽³⁾		10	50**	ns					
21	TioF	Port Output Fall Time ⁽³⁾		10	50**	ns					

TBD = To be determined.

- * These parameters are characterized but not tested.
- ** These parameters are design targets and are not tested.
- **Note 1:** Data in the Typical ("Typ") column is at 3.7V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
 - 2: Measurements are taken in EXTRC mode.
 - 3: See Figure 12-3 for loading conditions.

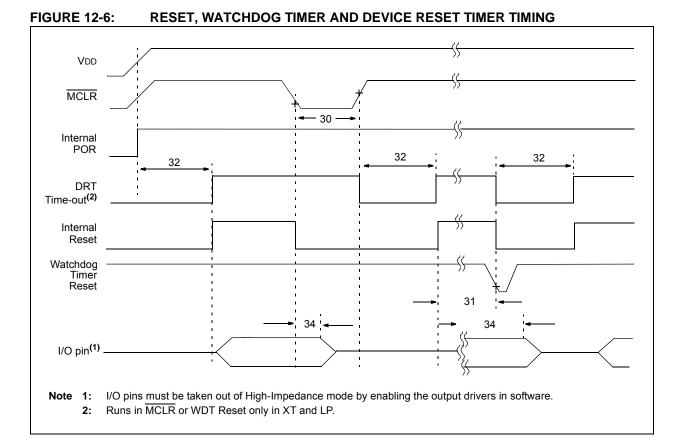


TABLE 12-8: RESET, WATCHDOG TIMER AND DEVICE RESET TIMER - PIC12F529T39A

AC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$ (industrial) Operating Voltage VDD range is described in Table 12-3.					
Param No. Characteristic				Тур ⁽¹⁾	Max.	Units	Conditions	
30	TMCL	MCLR Pulse Width (low)	2000*	_	_	ns	VDD = 3.0V	
31	TWDT	Watchdog Timer Time-out Period (no prescaler)	9*	20*	35*	ms	VDD = 3.0V (Industrial)	
32	TDRT	Device Reset Timer Period						
		Standard	9*	20*	35*	ms	V _{DD} = 3.0V (Industrial)	
		Short	0.5*	1.125*	2*	ms	V _{DD} = 3.0V (Industrial)	
34	Tioz	I/O High-impedance from MCLR low	_	_	2000*	ns		

^{*} These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 3.7V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 12-9: DRT (DEVICE RESET TIMER PERIOD)

Oscillator Configuration	POR Reset	Subsequent Resets		
IntRC and ExtRC	1 ms (typical)	10 μs (typical)		
XT and LP	18 ms (typical)	18 ms (typical)		

FIGURE 12-7: TIMERO CLOCK TIMINGS

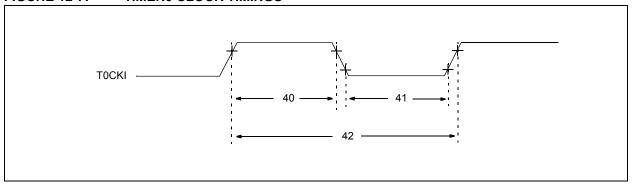


TABLE 12-10: TIMERO CLOCK REQUIREMENTS

AC CHARACTERISTICS			Operating Temp	Standard Operating Conditions (unless otherwise specified) Operating Temperature -40°C ≤ TA ≤ +85°C (industrial) Operating Voltage VDD range is described in Table 12-3.							
Param No. Characte			ristic	Typ ⁽¹⁾	Max.	Units	Conditions				
40	Tt0H	T0CKI High Pulse	No Prescaler	0.5 Tcy + 20*		_	ns				
		Width	With Prescaler	10*	_	_	ns				
41	TtOL	T0CKI Low Pulse	No Prescaler	0.5 Tcy + 20*	_	_	ns				
		Width	With Prescaler	10*	_	_	ns				
42 Tt0P T0CKI Period			20 or Tcy + 40* N	_	_	ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)				

These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 3.7V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 12-11: FLASH DATA MEMORY WRITE/ERASE REQUIREMENTS

AC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature -40°C ≤ TA ≤ +85°C (industrial) Operating Voltage VDD range is described in Table 12-2.					
Param No.	Sym.	Characteristic	Min.	Typ ⁽¹⁾	Max.	Units	Conditions	
43	Tow	Flash Data Memory Write Cycle Time	2	3.5	5	ms		
44	TDE	Flash Data Memory Erase Cycle Time	2	3	4	ms		

These parameters are characterized but not tested.

Note 1: Data in the Typical ("Typ") column is at 3.7V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

13.0 DC AND AC CHARACTERISTICS GRAPHS AND CHARTS

The graphs and tables provided in this section are for design guidance and are not tested.

In some graphs or tables, the data presented are **outside specified operating range** (i.e., outside specified VDD range). This is for **information only** and devices are ensured to operate properly only within the specified range.

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore, outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over each temperature range.

FIGURE 13-1: TYPICAL IDD vs. Fosc OVER VDD (XT, EXTRC mode)

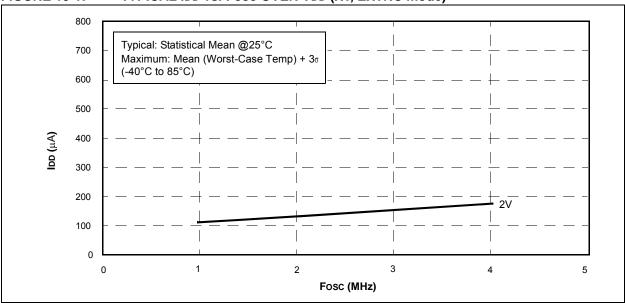
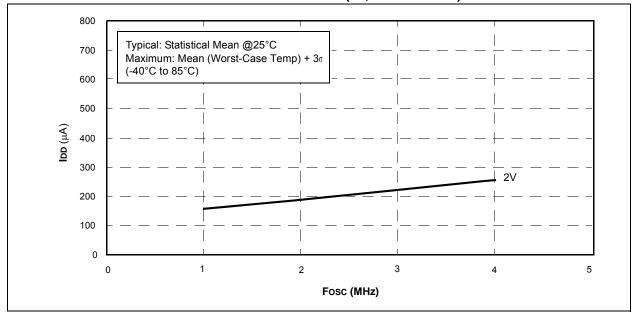


FIGURE 13-2: MAXIMUM IDD vs. FOSC OVER VDD (XT, EXTRC mode)



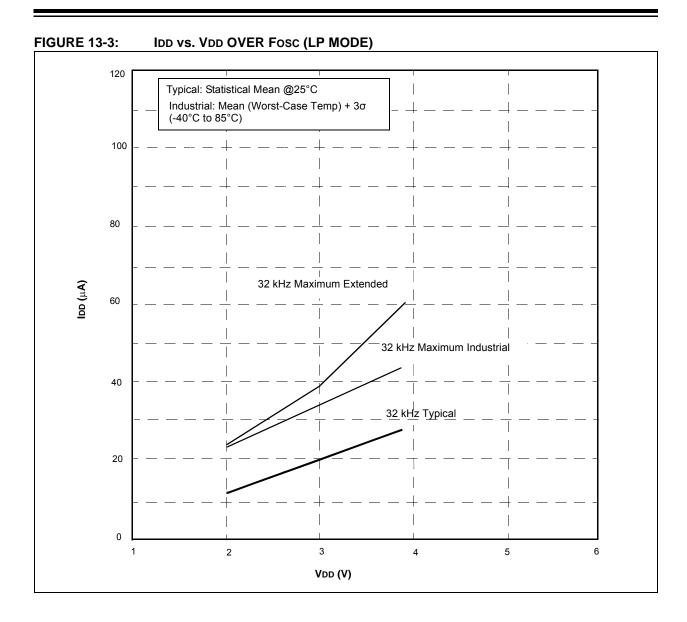


FIGURE 13-4: TYPICAL IPD vs. VDD (SLEEP MODE, ALL PERIPHERALS DISABLED)

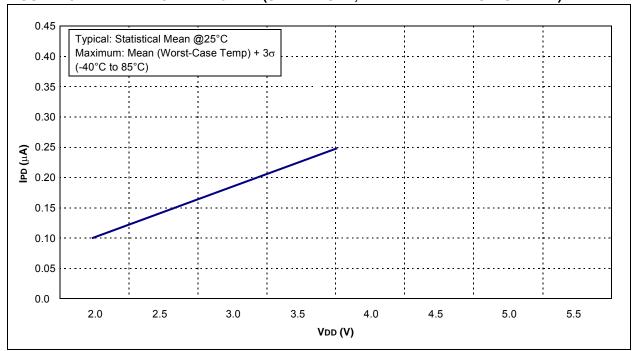
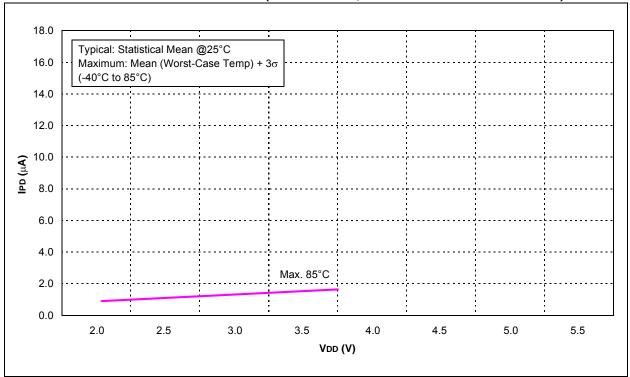
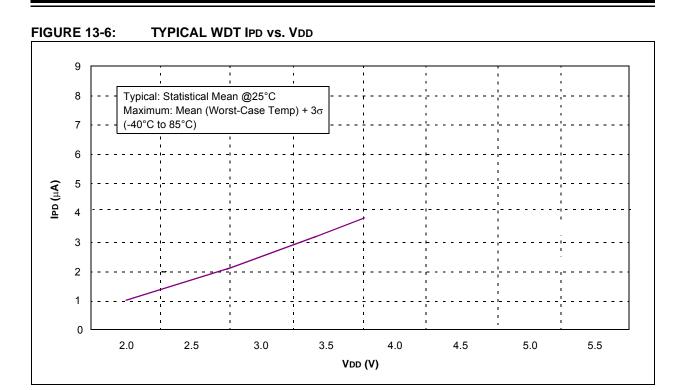
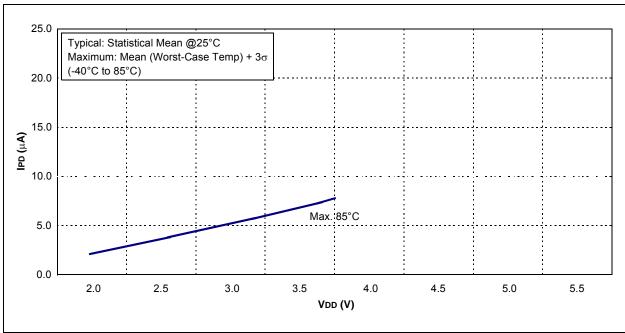


FIGURE 13-5: MAXIMUM IPD vs. VDD (SLEEP MODE, ALL PERIPHERALS DISABLED)









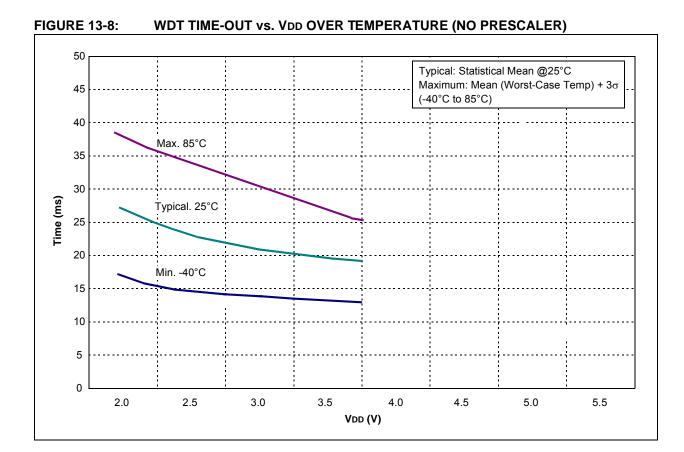


FIGURE 13-9: Vol vs. Iol OVER TEMPERATURE (VDD = 3.0V)

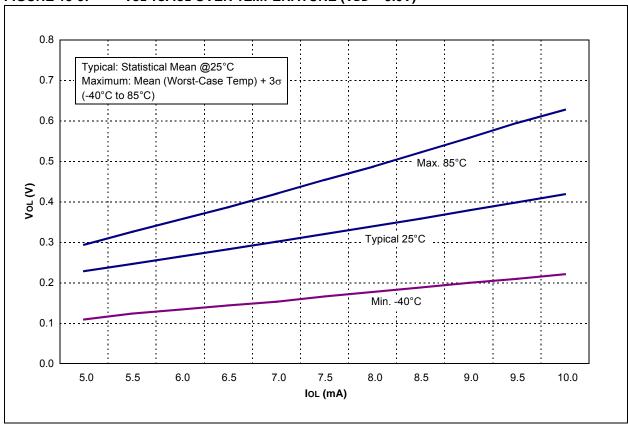


FIGURE 13-10: VOH vs. IOH OVER TEMPERATURE (VDD = 3.0V)

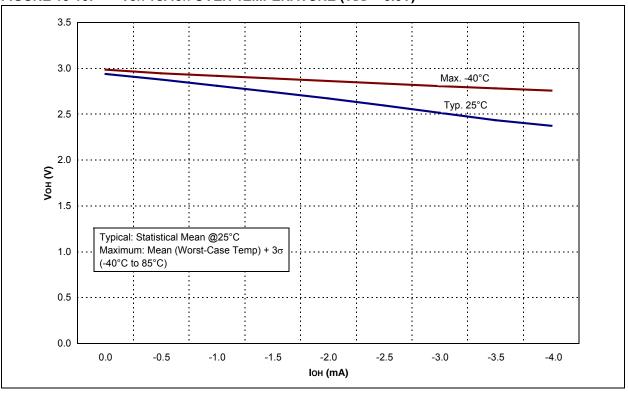


FIGURE 13-11: TTL INPUT THRESHOLD VIN vs. VDD

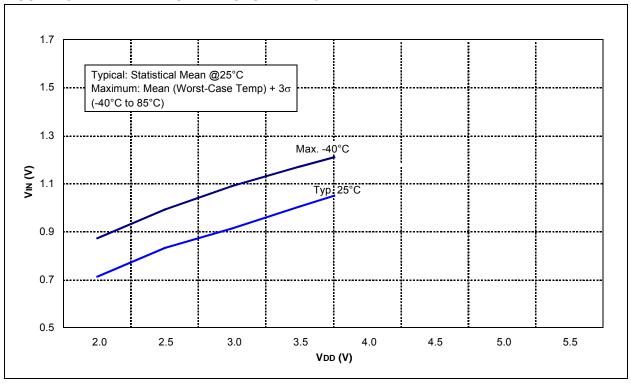
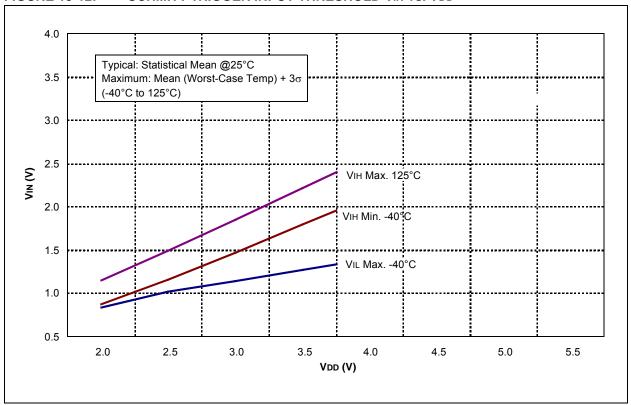
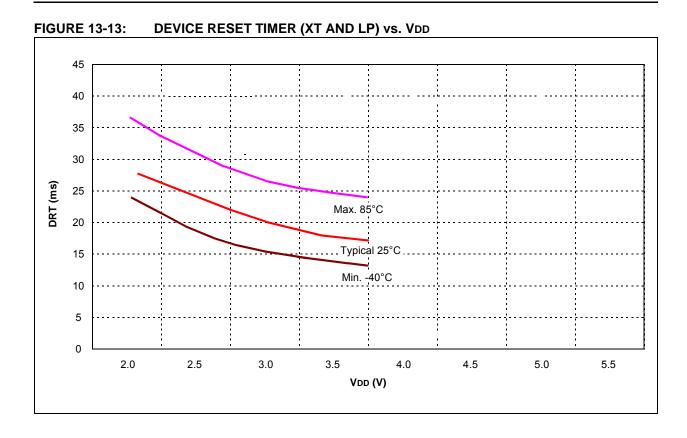


FIGURE 13-12: SCHMITT TRIGGER INPUT THRESHOLD VIN vs. VDD

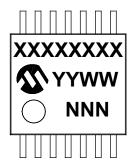


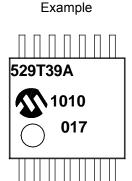


14.0 PACKAGING INFORMATION

14.1 **Package Marking Information**

14-Lead TSSOP (4.4 mm)





Legend: XX...X Customer-specific information

> Year code (last digit of calendar year) ΥY Year code (last 2 digits of calendar year) ww Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

This package is Pb-free. The Pb-free JEDEC designator (@3)

can be found on the outer packaging for this package.

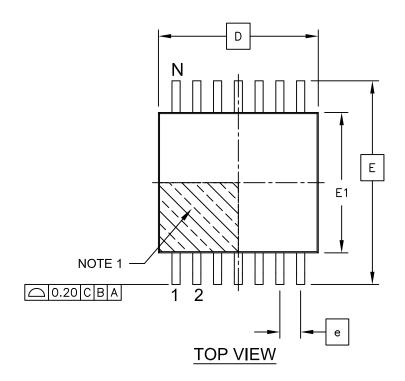
In the event the full Microchip part number cannot be marked on one line, it will Note: be carried over to the next line, thus limiting the number of available characters for customer-specific information.

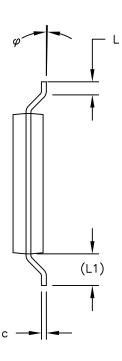
14.2 Package Details

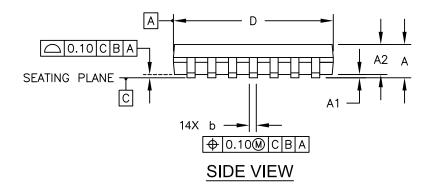
The following sections give the technical details of the packages.

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



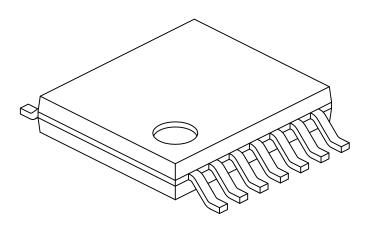




Microchip Technology Drawing C04-087C Sheet 1 of 2

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	N		14		
Pitch	е	0.65 BSC			
Overall Height	Α	-	-	1.20	
Molded Package Thickness	A2	0.80	1.00	1.05	
Standoff	A1	0.05	-	0.15	
Overall Width	E		6.40 BSC		
Molded Package Width	E1	4.30	4.40	4.50	
Molded Package Length	D	4.90	5.00	5.10	
Foot Length	L	0.45	0.60	0.75	
Footprint	(L1)	1.00 REF			
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.09		0.20	
Lead Width	b	0.19	-	0.30	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M

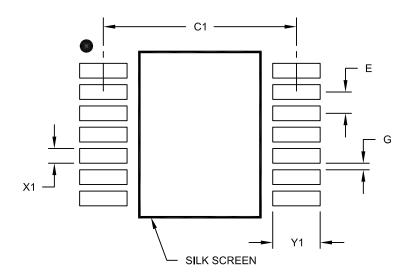
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-087C Sheet 2 of 2

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X14)	X1			0.45
Contact Pad Length (X14)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2087A

APPENDIX A: DATA SHEET

REVISION HISTORY

Revision A (05/2012)

Initial release.

Revision B (01/2015)

Updated Register 8-1 and Table 9-3; Other minor corrections.

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PART NO. Device	[X] ⁽¹⁾ - X /XX XXX Tape and Reel Option Temperature Package Pattern Range Pattern Package
Device:	PIC12F529T39A
Tape and Reel Option:	Blank = Standard packaging (tube or tray) T = Tape and Reel ⁽¹⁾
Temperature Range:	I = -40 °C to $+85$ °C (Industrial)
Package:	ST = TSSOP
Pattern:	QTP, SQTP, Code or Special Requirements (blank otherwise)

Examples:

a) PIC12F529T39AT - I/ST 301 Tape and Reel, Industrial temperature, TSSOP package QTP pattern #301

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

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